

Base width modulation or Early Effect  $\Rightarrow$  The output current is depend upon the input current as well as output voltage.

Page No. \_\_\_\_\_

Date: \_\_\_\_\_

## BJT as an Amplifier & as a Switch

$$V_o = V_{cc} - i_c R_c$$

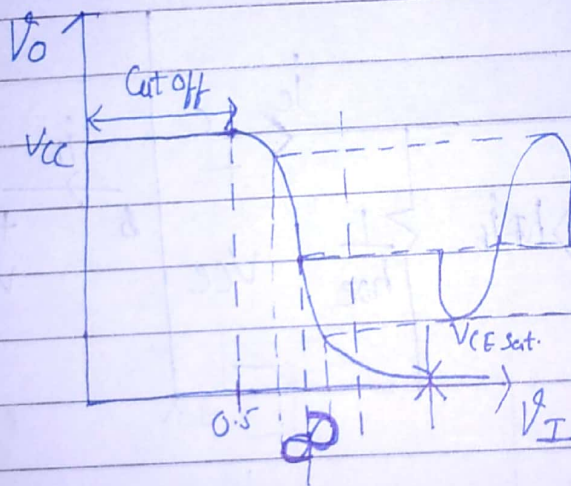
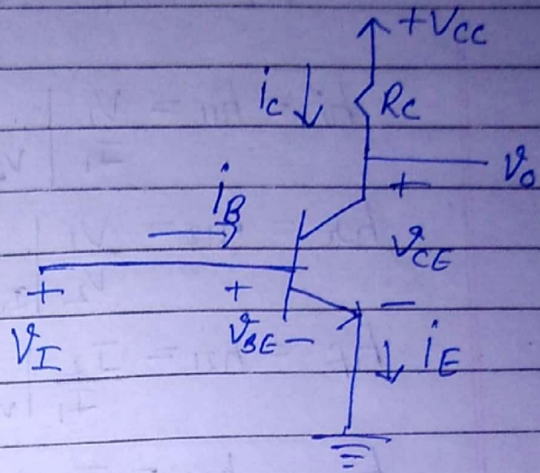
$$V_o = V_{cc} - I_s e^{V_{be}/V_T} R_c$$

$$V_o = V_{cc} - I_s e^{V_I/V_T} R_c$$

for  $V_I \leq 0.5V$

$$V_o = V_{cc}$$

for  $V_I > 0.5V$



$$V_o = V_{cc} - I_s e^{V_I/V_T} R_c$$

$$\frac{dV_o}{dV_I} = 0 - I_s e^{V_I/V_T} \cdot \frac{1}{V_T} \cdot R_c$$

$$A_v = \frac{-R_c}{V_T} \left[ I_s e^{V_I/V_T} \right]$$

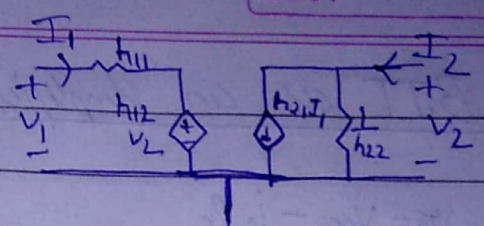
$$A_v = \frac{-R_c i_c}{V_T} = -\frac{V_{RC}}{V_T}$$

-ve sign indicates that input & output phase difference is  $180^\circ$ .

3/09/19

$$V_1 = h_{11}I_1 + h_{12}V_2$$

$$I_2 = h_{21}I_1 + h_{22}V_2$$

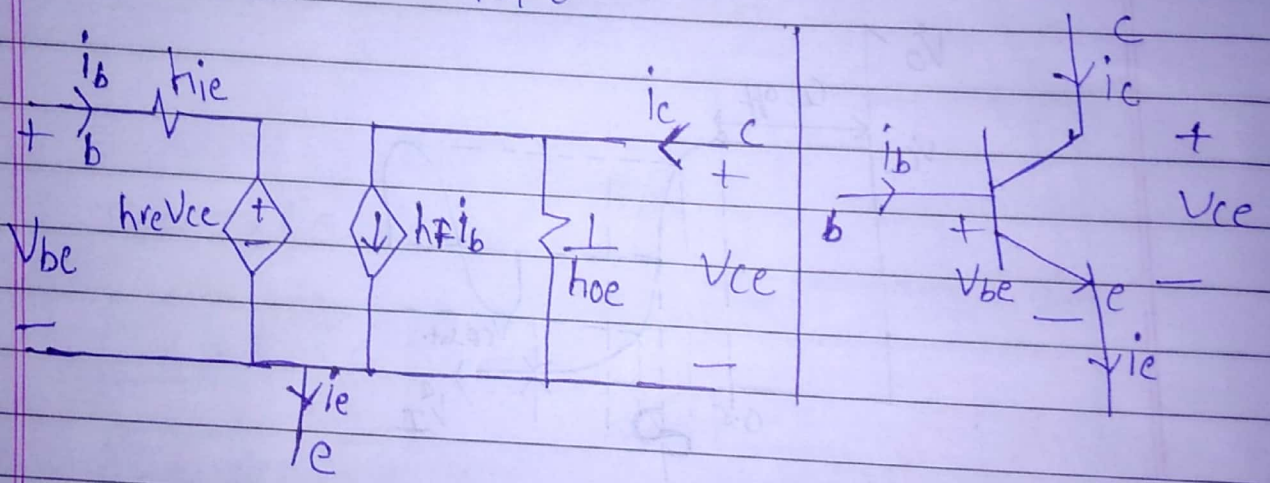


$h_i = h_{11} = \frac{V_1}{I_1} \Big|_{V_2=0}$   $\Rightarrow$  short ckt. i/p impedance

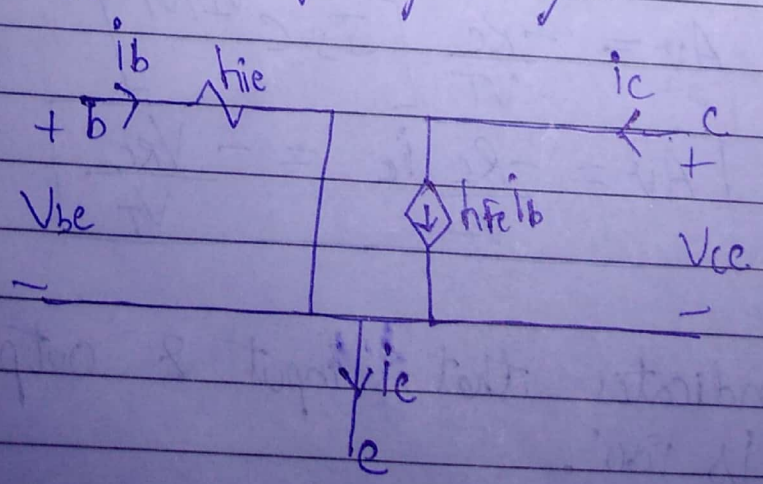
$h_r = h_{12} = \frac{V_1}{V_2} \Big|_{I_1=0}$   $\Rightarrow$  open ckt. -reverse transfer voltage gain

$h_f = h_{21} = \frac{I_2}{I_1} \Big|_{V_2=0}$   $\Rightarrow$  short ckt. forward transfer current gain

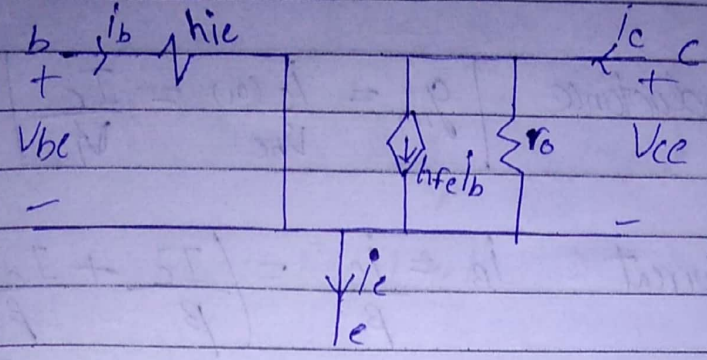
$h_o = h_{22} = \frac{I_2}{V_2} \Big|_{I_1=0}$   $\Rightarrow$  open ckt. O/P admittance



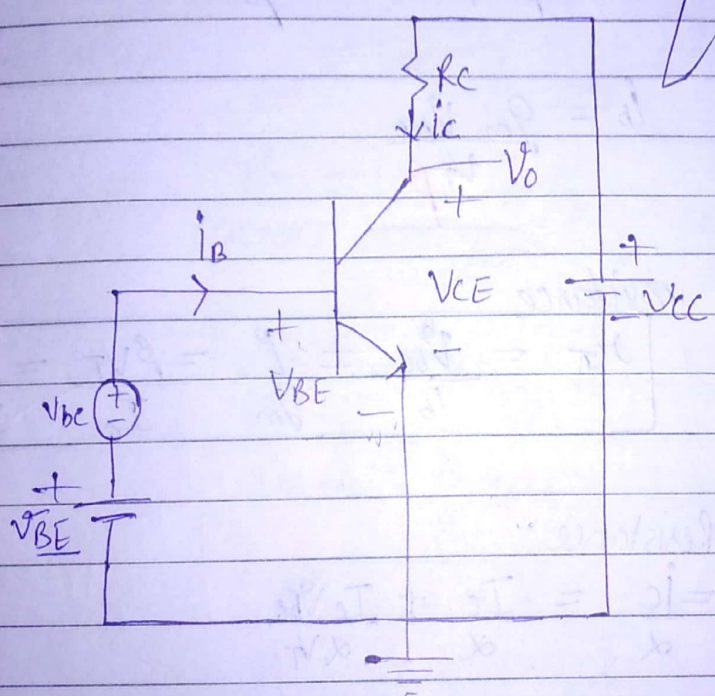
$h_{re}$  is very-very small  
 $\frac{1}{h_{oe}}$  is very-very large



$r_o$  is connected to show the effect of base width modulation.



Small signal operation & Model



$$V_{BE} = v_{be} + V_{BE}$$

$$i_c = I_s e^{V_{BE}/V_T} = I_s e^{(V_{be} + V_{BE})/V_T}$$

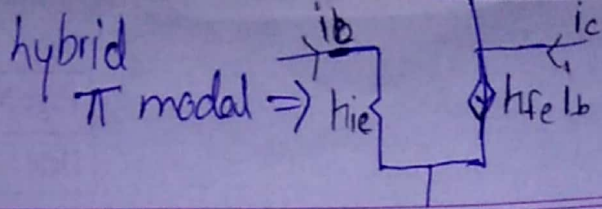
(ac+dc)

$$= I_s e^{V_{BE}/V_T} \cdot e^{v_{be}/V_T}$$

$$i_c = I_c e^{v_{be}/V_T}$$

$$\therefore v_{be} \ll V_T$$

$$i_c = I_c \left[ 1 + \frac{v_{be}}{V_T} \right] = \underbrace{I_c}_{DC} + \underbrace{I_c \frac{v_{be}}{V_T}}_{ac}$$



Page No.

Date:

$$i_c = \frac{I_c V_{be}}{V_T}$$

(ac)

Transconductance

$$g_m = \frac{i_c(\text{ac})}{V_{be}} = \frac{I_c}{V_T}$$

Base Current

$$i_b = \frac{i_c}{\beta} = \left( \frac{I_c}{\beta} + \frac{I_c V_{be}}{\beta V_T} \right)$$

dc ac

$$i_b = \frac{I_c V_{be}}{\beta V_T} = \frac{g_m V_{be}}{\beta}$$

$$i_b = \frac{g_m V_{be}}{\beta}$$

base  $\#$  resistance

$$r_{\pi} = \frac{V_{be}}{i_b} = \frac{\beta}{g_m} = \frac{\beta V_T}{I_c} = \frac{V_T}{I_B}$$

25/09/19

Emitter Resistance

$$i_E = \frac{i_c}{\alpha} = \frac{I_c}{\alpha} + \frac{I_c V_{be}}{\alpha V_T}$$

ac+dc

$$i_E = I_E + \frac{I_c V_{be}}{\alpha V_T}$$

ac+dc dc ac

$$i_e = \frac{I_c V_{be}}{\alpha V_T}$$

Emitter resistance ( $r_e$ ) =  $\frac{V_{be}}{i_e}$

$$r_e = \frac{\alpha V_T}{I_c} = \frac{\alpha}{g_m} = \frac{V_T}{I_E}$$

$$r_{\pi} > r_e$$

$$r_{\pi} = \frac{\beta}{g_m} = \left(\frac{\alpha}{1-\alpha}\right) \frac{1}{g_m}$$

$$\boxed{r_{\pi} = \frac{r_e}{1-\alpha}} = \frac{r_e}{\frac{1-\beta}{1+\beta}} = \frac{r_e(1+\beta)}{1-\beta}$$

$$\boxed{r_{\pi} = (1+\beta)r_e}$$

Gain

$$V_o = V_{cc} - i_c r_c$$

(ac+dc)                      (ac+dc)

$$= V_{cc} - \left[ I_c + I_c \frac{V_{be}}{V_T} \right] R_c$$

$$V_o = V_{cc} - \underbrace{I_c R_c}_{dc} - \underbrace{I_c \frac{V_{be} R_c}{V_T}}_{ac}$$

$$V_o = - \frac{I_c V_{be} R_c}{V_T}$$

(ac)

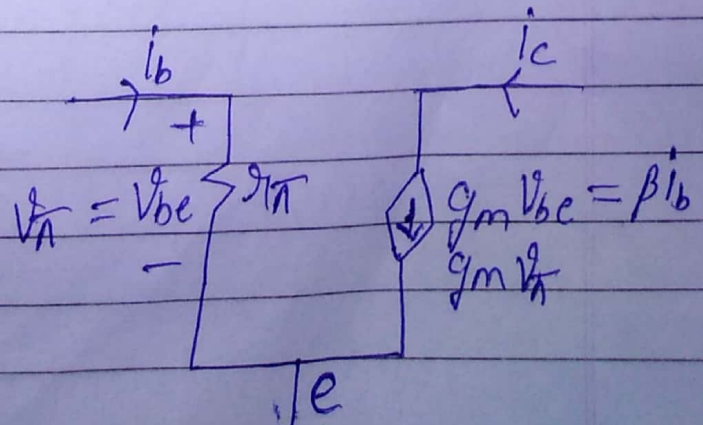
$$G_{\text{gain}} = \frac{V_o(ac)}{V_{be}} = - \frac{I_c R_c}{V_T}$$

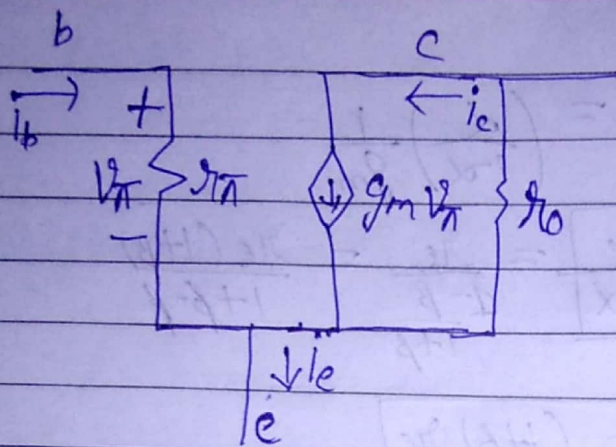
$$\boxed{G_{\text{gain}} = - \frac{V_{RC}}{V_T}}$$

$$\boxed{G_{\text{gain}} = -g_m R_c}$$

-ve sign indicates that 180° phase diff. b/w input & output.

Hybrid-π Model



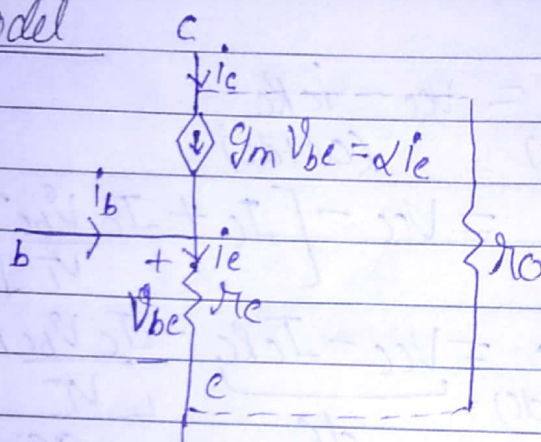


$$i_c = I_C + I_C \frac{V_{be}}{V_T}$$

$$g_m V_{be} = \frac{I_C V_{be}}{V_T} = \frac{\beta I_B V_{be}}{V_T}$$

$$= \beta \frac{V_{be}}{r_{\pi}} = \frac{\beta I_B r_{\pi}}{V_T}$$

T-Model



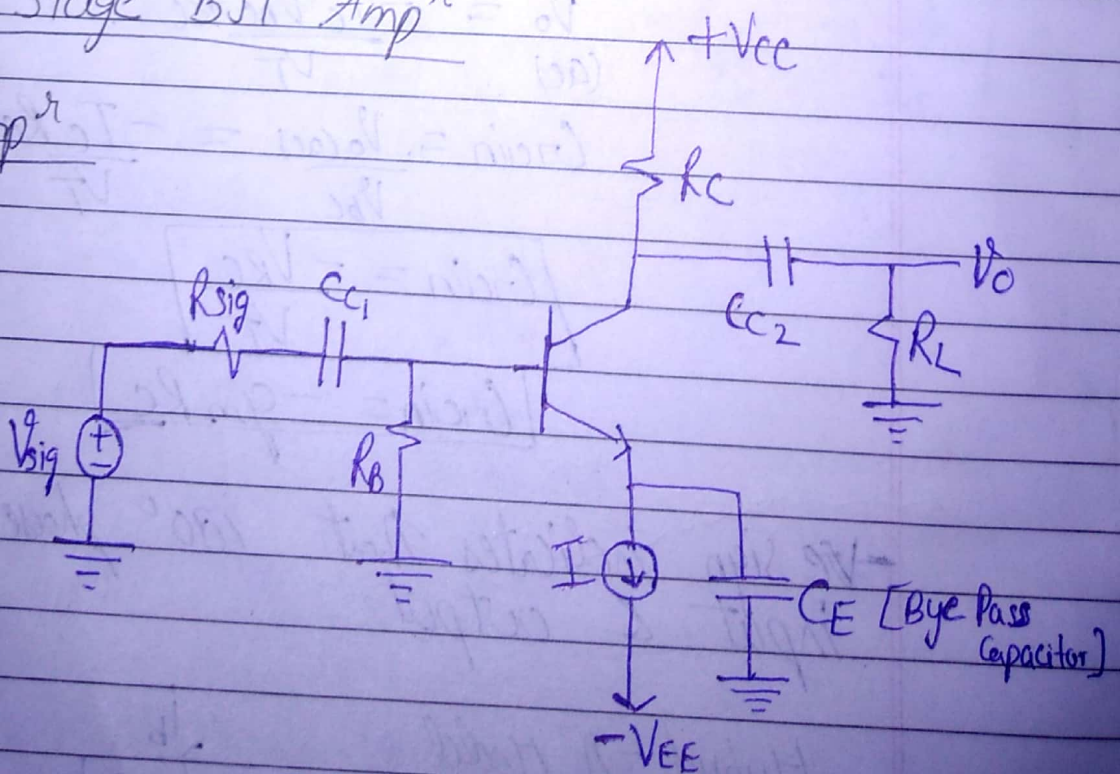
$$g_m V_{be} = \frac{I_C V_{be}}{V_T} = \frac{\alpha I_E V_{be}}{V_T}$$

$$= \alpha \frac{V_{be}}{r_c} = \frac{\alpha i_e r_e}{r_c}$$

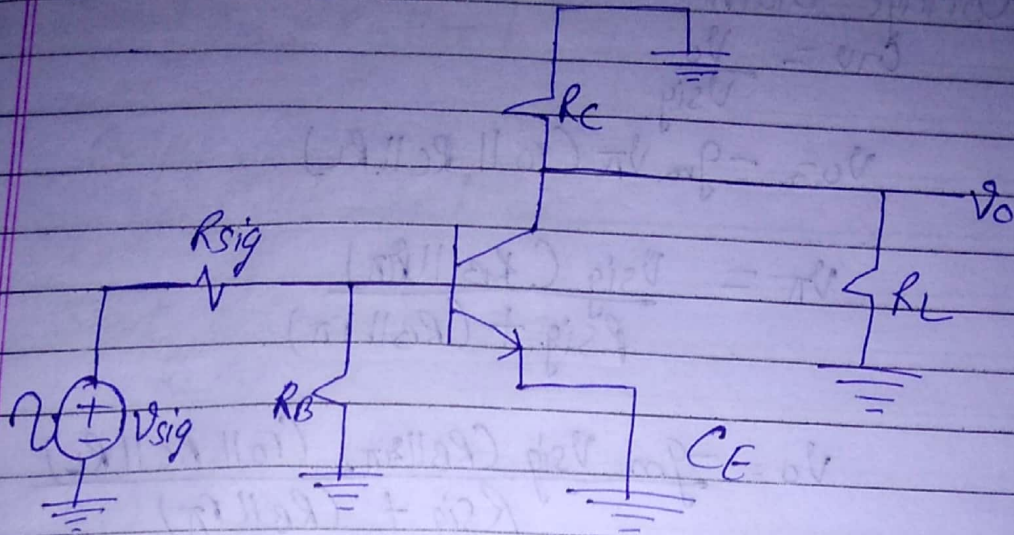
$$= \alpha i_e$$

Single Stage BJT Amp<sup>r</sup>

1) C:E Amp<sup>r</sup>

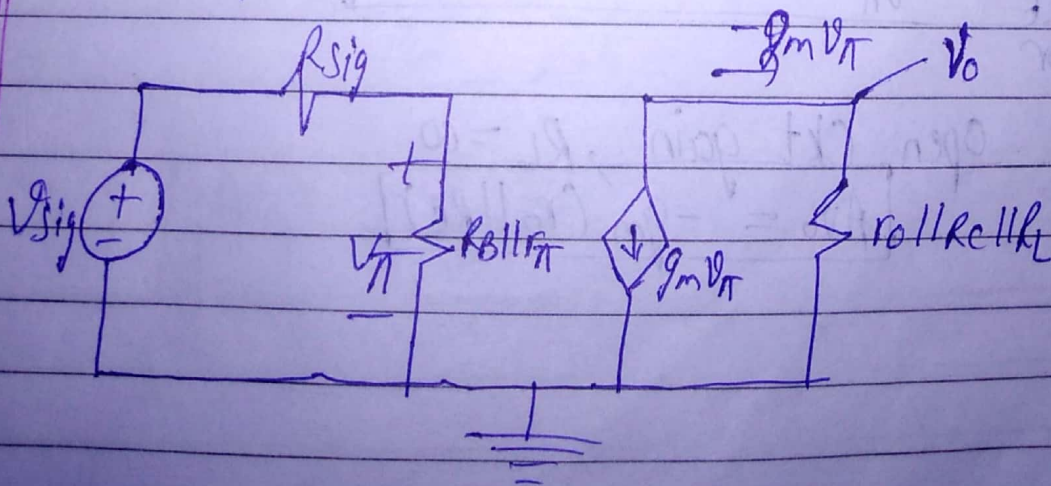
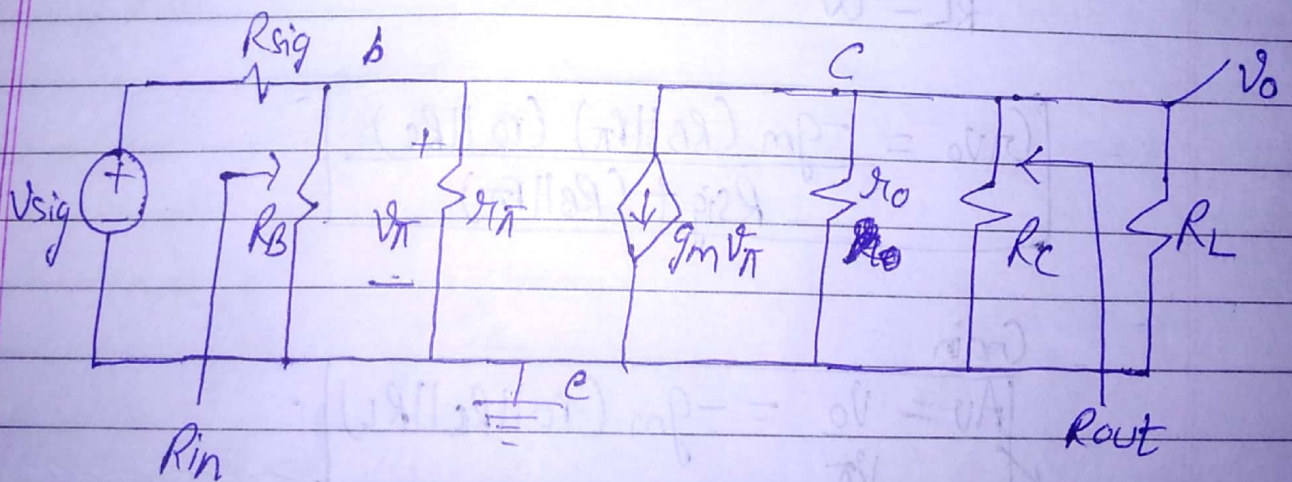


27/09/19



$$X_C = \frac{1}{2\pi f C}$$

DC analysis  
 $f = 0$



Voltage Gain

$$G_{vo} = \frac{V_o}{V_{sig}}$$

$$V_o = -g_m v_{\pi} (r_o \parallel R_c \parallel R_L)$$

$$v_{\pi} = \frac{V_{sig} (R_B \parallel r_{\pi})}{R_{sig} + (R_B \parallel r_{\pi})}$$

$$V_o = \frac{-g_m V_{sig} (R_B \parallel r_{\pi}) (r_o \parallel R_c \parallel R_L)}{R_{sig} + (R_B \parallel r_{\pi})}$$

overall gain  $\left\{ G_{vo} = \frac{V_o}{V_{sig}} = \frac{-g_m (R_B \parallel r_{\pi}) (r_o \parallel R_c \parallel R_L)}{R_{sig} + (R_B \parallel r_{\pi})} \right.$

open ckt gain  
 $R_L = \infty$

$$G_{vo} = \frac{-g_m (R_B \parallel r_{\pi}) (r_o \parallel R_c)}{R_{sig} + (R_B \parallel r_{\pi})}$$

Gain

$$A_v = \frac{V_o}{v_{\pi}} = -g_m (r_o \parallel R_c \parallel R_L)$$

Transistor  
Gain

open ckt gain,  $R_L = \infty$

$$A_{vo} = -g_m (r_o \parallel R_c)$$



Input resistance

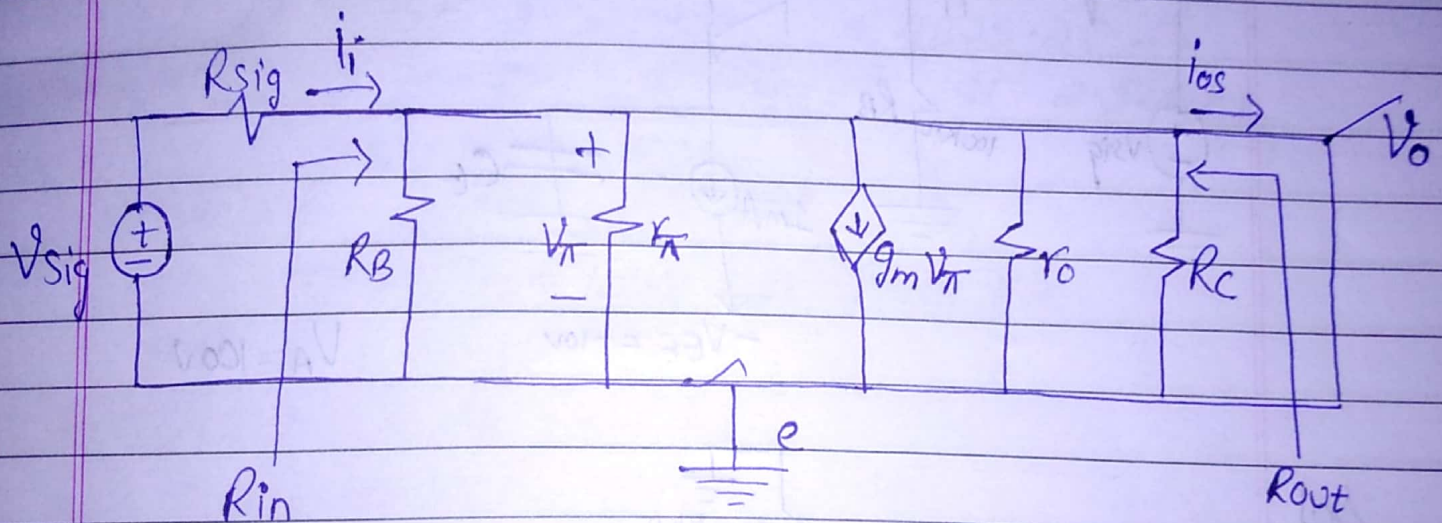
$$R_{in} = R_B \parallel r_{\pi}$$

Output Resistance

$$R_{out} = R_C \parallel r_o$$

Short ckt current gain

$$R_L = 0$$



$$A_{is} = \frac{i_{os}}{i_i}$$

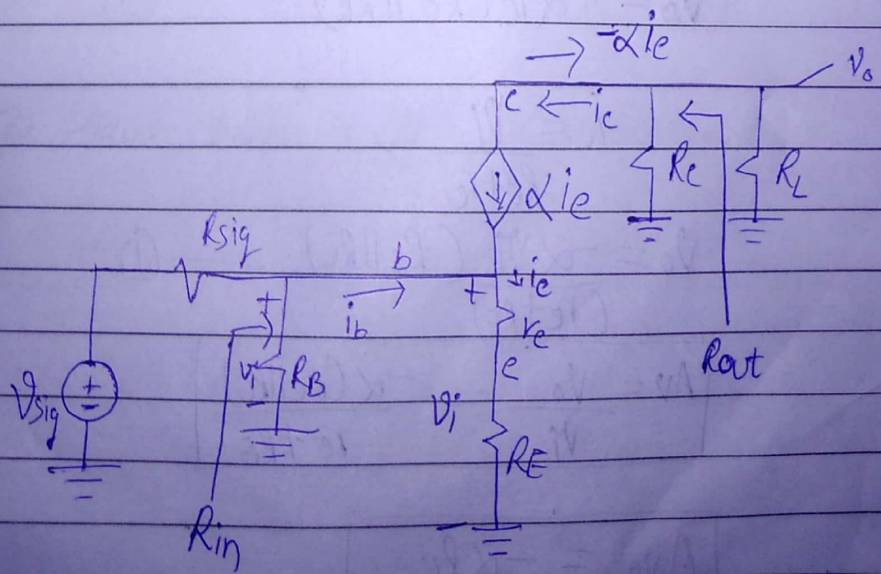
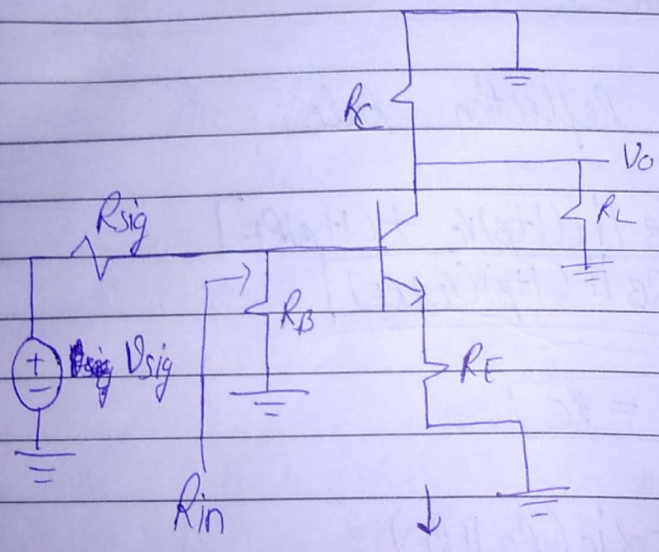
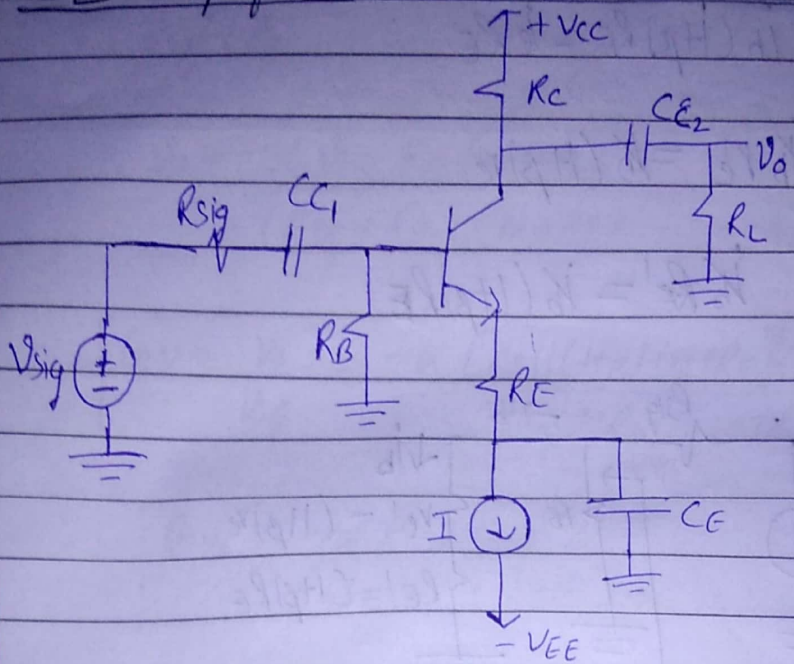
$$i_{os} = -g_m v_{\pi}$$

$$i_i = \frac{v_{in}}{R_{in}} = \frac{v_{\pi}}{R_B \parallel r_{\pi}}$$

$$A_{is} = \frac{-g_m v_{\pi}}{v_{\pi} / (R_B \parallel r_{\pi})} = -g_m (R_B \parallel r_{\pi})$$

01/10/19

# CE amplifier with emitter resistance

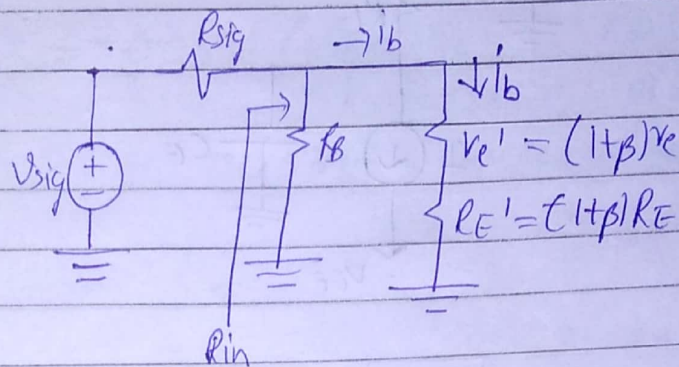


$$i_b(1+\beta)r_e = i_e r_e$$

$$i_b(1+\beta)R_E = i_e R_E$$

$$i_b r_e = i_b(1+\beta)r_e$$

$$i_b R_E' = i_b(1+\beta)R_E$$



Resistance Reflection Rule

$$R_{in} = R_B \parallel [(1+\beta)r_e + (1+\beta)R_E]$$

$$R_{in} = R_B \parallel (1+\beta)(r_e + R_E)$$

$$R_{out} = R_C$$

$$v_o = -\alpha i_e (R_C \parallel R_L)$$

$$i_e = \frac{v_i}{R_E + r_e}$$

$$v_o = \frac{-\alpha v_i (R_C \parallel R_L)}{R_E + r_e} \quad \text{--- (1)}$$

$$A_v = \frac{v_o}{v_i} = \frac{-\alpha (R_C \parallel R_L)}{R_E + r_e}$$

$$A_{v0} = \frac{-\alpha R_C}{R_E + r_e}$$

$R_{in} \uparrow, R_{out} \downarrow, G_{v} \downarrow \Rightarrow$  for voltage amplifier

Page No.

Date:

$$V_i = \frac{V_{sig}}{R_{sig} + R_{in}} \times R_{in}$$

$$V_o = \frac{-\alpha V_{sig} R_{in} (R_c \parallel R_L)}{(R_{sig} + R_{in})(r_e + R_E)}$$

$$G_{v} = \frac{V_o}{V_{sig}} = \frac{-\alpha [R_B \parallel (1 + \beta)(r_e + R_E)] (R_c \parallel R_L)}{(R_{sig} + R_{in})(r_e + R_E)}$$

$$G_{v_o} = \frac{-\alpha R_{in} R_c}{(R_{sig} + R_{in})(r_e + R_E)}$$

Short Ckt Current Gain

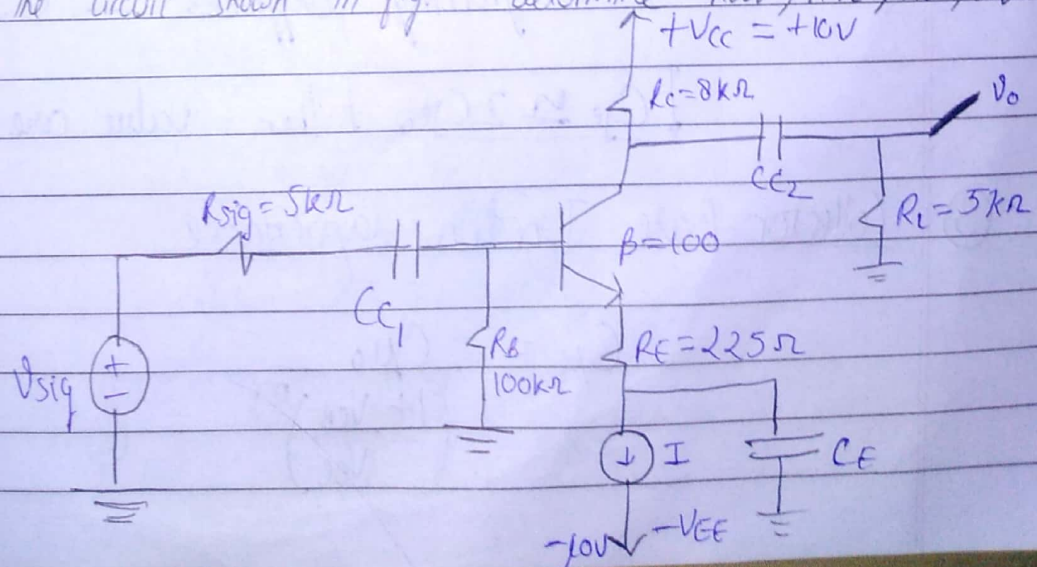
$$A_{i_s} = \frac{i_{os}}{i_i}$$

$$i_{os} = -\alpha i_e$$

$$i_i = \frac{V_i}{R_{in}} = \frac{i_e (R_E + r_e)}{R_{in}}$$

$$A_{i_s} = \frac{-\alpha i_e}{i_e (R_E + r_e) / R_{in}} = \frac{-\alpha R_{in}}{R_E + r_e}$$

Q For The circuit shown in fig: determine  $R_{out}, A_{v_o}, A_v, G_{v}$  &  $A_{i_s}$ .



03/10/19

Page No.

Date:

## BJT Internal Capacitance

### ① Base Charging Capacitance or Diffusion Capacitance

$$Q_{**} = \tau_F I_C$$

↓  
Forward  
Transit time

$$C_{de} = \frac{dQ}{dV_{BE}} = \tau_F \frac{dI_C}{dV_{BE}} = \tau_F \frac{d}{dV_{BE}} (I_S e^{V_{BE}/V_T})$$

$$= \tau_F I_S e^{V_{BE}/V_T} \cdot \frac{1}{V_T}$$

$$C_{de} = \tau_F \frac{I_C}{V_T} = \tau_F \frac{(I_C + i_c)}{V_T} \approx \tau_F \frac{I_C}{V_T} \approx \tau_F g_m$$

### ② Emitter Base Junction Capacitance

$$C_{je} = \frac{C_{je0}}{(1 - V_{BE}/V_{be})^m}$$

where  $C_{je0}$  = Value of  $C_{je}$  at  $V_{BE} = 0$   
 $V_{be}$  = Emitter Base Junction built in voltage.  
 $\approx 0.9V$

$m$  = grading coefficient  $\approx 0.5$

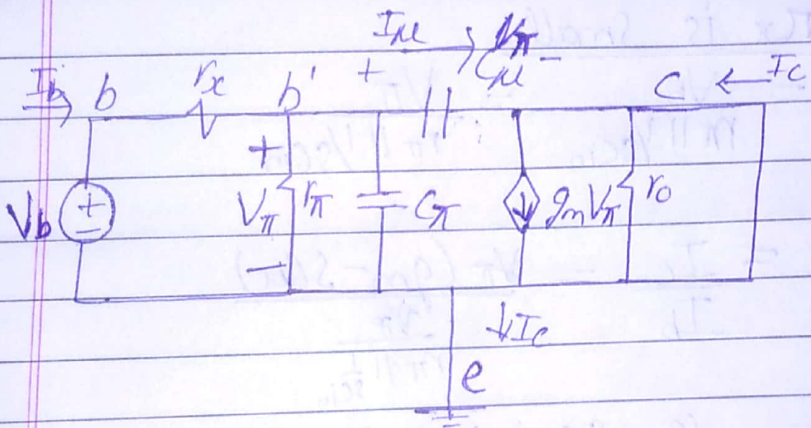
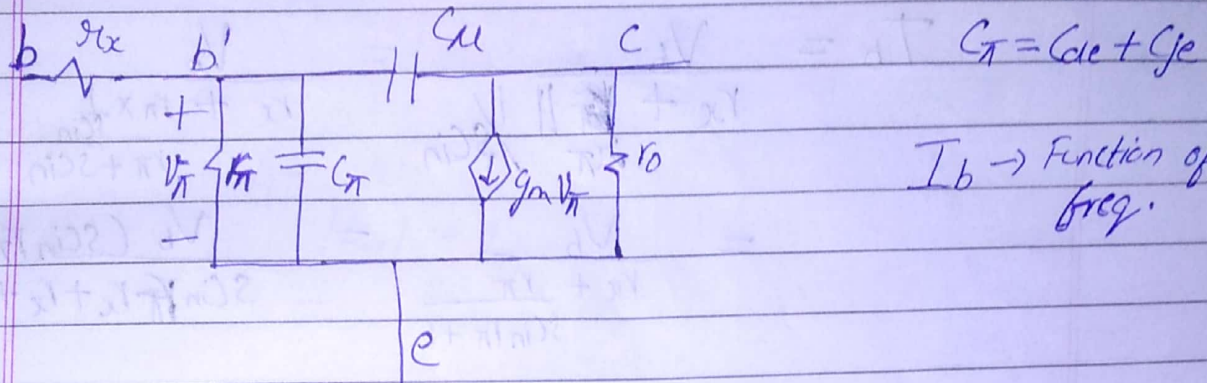
$C_{je} \approx 2C_{je0}$  then value are not given

### ③ Collector Base Junction Capacitance

$$C_{jc} = \frac{C_{jc0}}{\left(1 + \frac{V_{cb}}{V_{oc}}\right)^m}$$

where  $C_{u0}$  = Value of  $C_u$  at  $V_{cb} = 0$   
 $V_{oc}$  = CBJ built in voltage  $\approx 0.75V$   
 $m$  = grading coefficient  $\approx 0.2 - 0.5$

04/10/19 High frequency model



Short ckt current gain

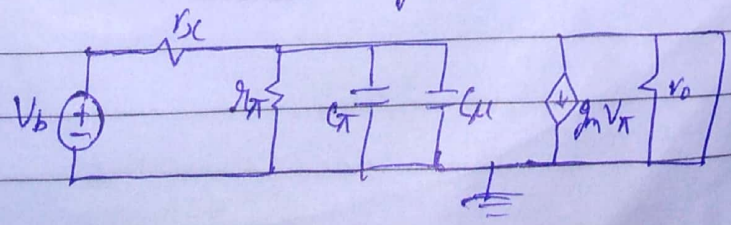
Current gain =  $\frac{I_c}{I_b}$

$I_c + I_{cu} = g_m V_{\pi}$

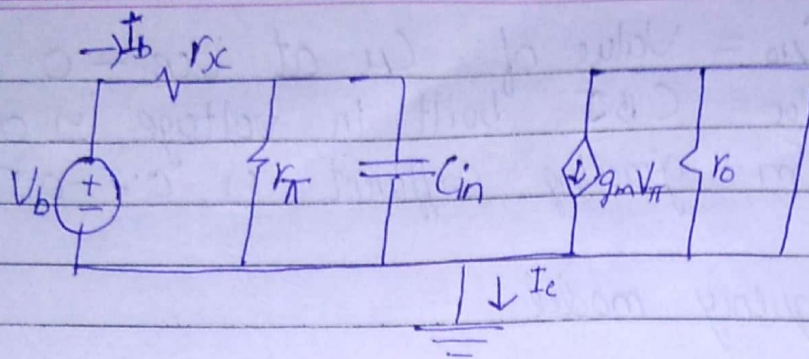
$I_c = g_m V_{\pi} - I_{cu}$

$I_c = g_m V_{\pi} - \frac{V_{\pi}}{R_{cu}} \Rightarrow g_m V_{\pi} - s C_u V_{\pi}$

$I_c = V_{\pi} (g_m - s C_u)$



$$C_{in} = C_{\pi} + C_{\mu}$$



$$I_b = \frac{V_b}{r_x + r_{\pi} \parallel \frac{1}{sC_{in}}} = \frac{V_b}{r_x + \frac{r_{\pi} \times \frac{1}{sC_{in}}}{r_{\pi} + \frac{1}{sC_{in}}}}$$

$$= \frac{V_b}{r_x + \frac{r_{\pi}}{sC_{in}r_{\pi} + 1}} = \frac{V_b (sC_{in}r_{\pi} + 1)}{sC_{in}r_{\pi}r_x + r_x + r_{\pi}}$$

$I_c$  is small

$$I_b = \frac{V_b}{r_{\pi} \parallel \frac{1}{sC_{in}}} = \frac{V_{\pi}}{r_{\pi} \parallel \frac{1}{sC_{in}}}$$

$$h_{fe} = \frac{I_c}{I_b} = \frac{V_{\pi} (g_m - sC_{\mu})}{\frac{V_{\pi}}{r_{\pi} \parallel \frac{1}{sC_{in}}}}$$

$$= (g_m - sC_{\mu}) r_{\pi} \parallel \frac{1}{sC_{in}}$$

$$= (g_m - sC_{\mu}) \left( \frac{r_{\pi} \times \frac{1}{sC_{in}}}{r_{\pi} + \frac{1}{sC_{in}}} \right)$$

$$h_{fe} = \frac{(g_m - sC_{\mu}) r_{\pi}}{(sC_{in} r_{\pi} + 1)}$$

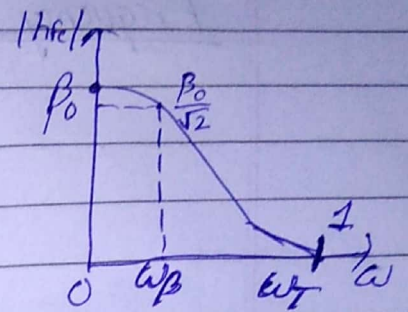
$$g_m \gg sC_{\mu}$$

$$h_{fe} = \frac{g_m r_{\pi}}{(sC_{in} r_{\pi} + 1)}$$

$$h_{fe} = \frac{\beta_0}{s C_{in} r_{\pi} + 1} \quad \therefore r_{\pi} = \frac{\beta}{g_m}$$

$$|h_{fe}| = \frac{\beta_0}{j\omega C_{in} r_{\pi} + 1}$$

$$|h_{fe}| = \frac{\beta_0}{\sqrt{(\omega C_{in} r_{\pi})^2 + 1}}$$



$$\text{At } \omega = \omega_T$$

$$|h_{fe}| = 1$$

$$1 = \frac{\beta_0}{\sqrt{(\omega_T C_{in} r_{\pi})^2 + 1}}$$

$$\beta_0^2 = (\omega_T C_{in} r_{\pi})^2 + 1$$

$$\beta_0^2 - 1 = (\omega_T C_{in} r_{\pi})^2$$

$$\boxed{\omega_T = \frac{\sqrt{\beta_0^2 - 1}}{C_{in} r_{\pi}}}$$

$$\boxed{\omega_T \approx \frac{\beta_0}{C_{in} r_{\pi}}}$$

$$\text{At } \omega = \omega_{\beta}$$

$$|h_{fe}| = \frac{\beta_0}{\sqrt{2}} = 0.707 \beta_0$$

$$\frac{\beta_0}{\sqrt{(\omega_{\beta} C_{in} r_{\pi})^2 + 1}} = \frac{\beta_0}{\sqrt{2}}$$

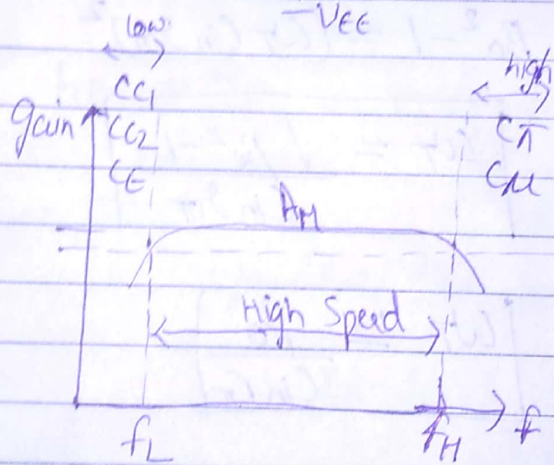
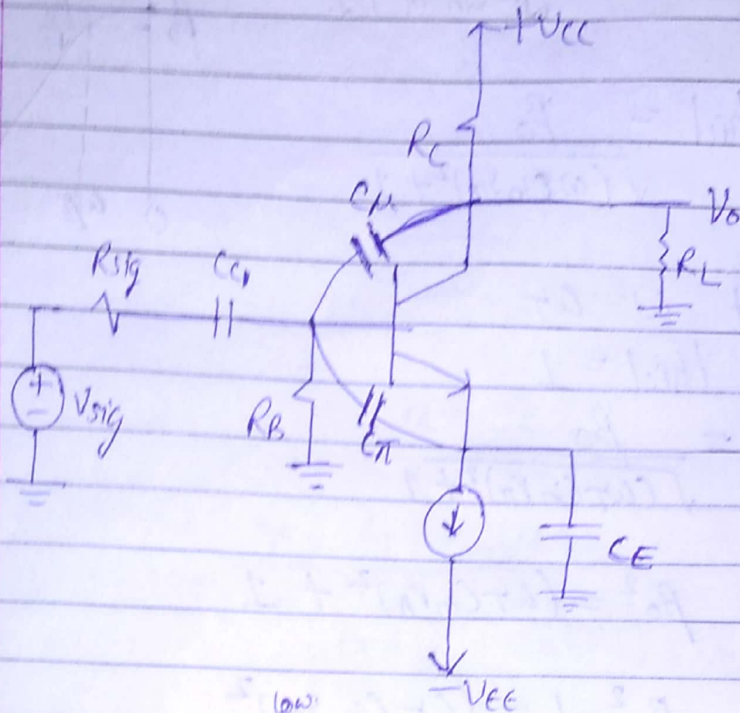
$$2 = (\omega_{\beta} C_{in} r_{\pi})^2 + 1$$

$$\boxed{\omega_{\beta} = \frac{1}{C_{in} r_{\pi}}}$$



$$BW = \beta \omega \beta$$

### Frequency Response of CE Amp<sup>2</sup>

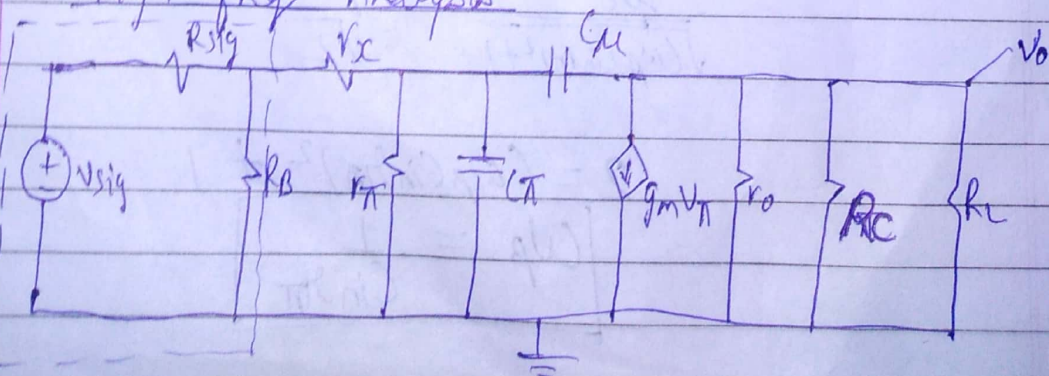


$$BW = \uparrow \omega_H - \omega_L \downarrow$$

$$BW = \uparrow f_H - f_L \downarrow$$

### High freq. Analysis

Apply T.T



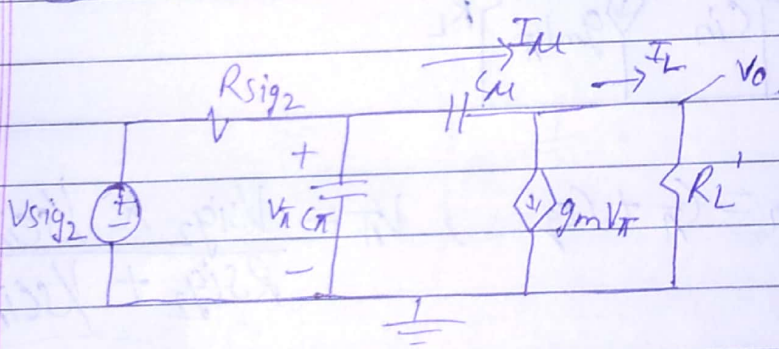
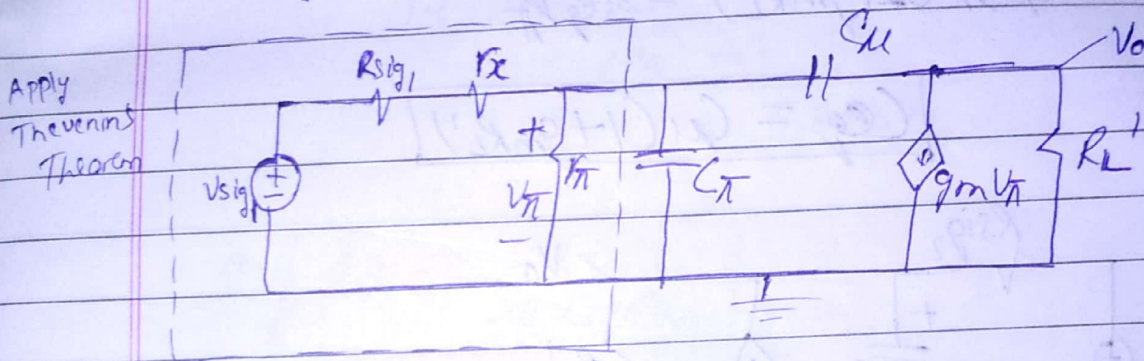
$$R_L' = r_o \parallel R_c \parallel R_L$$

$$V_{sig_1} = \frac{V_{sig} R_B}{R_{sig} + R_B}$$

$$R_{sig_1} = R_{sig} \parallel R_B$$

$$V_{sig_2} = \frac{V_{sig_1} r_{\pi}}{R_{sig_1} + r_x + r_{\pi}}$$

$$R_{sig_2} = (R_{sig_1} + r_x) \parallel r_{\pi}$$



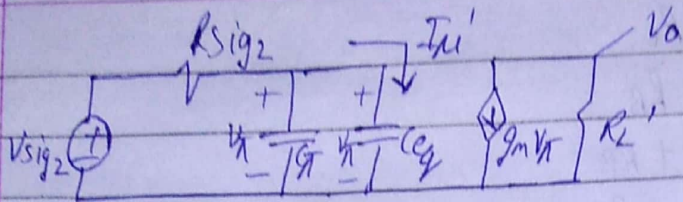
$$I_L = I_{\mu} - g_m V_{\pi}$$

$$V_o = I_L R_L' = (I_{\mu} - g_m V_{\pi}) R_L' \approx -g_m V_{\pi} R_L' \quad (g_m V_{\pi} \gg I_{\mu})$$

$$I_{\mu} = \frac{V_{\pi} - V_o}{\frac{1}{s C_{\mu}}} = s C_{\mu} (V_{\pi} - V_o)$$

$$I_{\mu} = s C_{\mu} (V_{\pi} + g_m V_{\pi} R_L')$$

$$I_{\mu} = s C_{\mu} V_{\pi} (1 + g_m R_L')$$

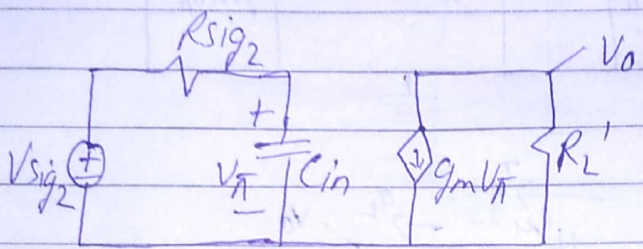


$$I_{\pi}' = \frac{V_{\pi}}{\frac{1}{sC_{eq}}} = sC_{eq} V_{\pi}$$

$$I_{\pi} = I_{\pi}'$$

$$sC_{\pi} V_{\pi} (1 + g_m R_L') = sC_{eq} V_{\pi}$$

$$C_{eq} = C_{\pi} (1 + g_m R_L')$$



$$C_{in} = C_{\pi} + C_{eq}, \quad V_{\pi} = \frac{V_{sig2} \times \frac{1}{sC_{in}}}{R_{sig2} + \frac{1}{sC_{in}}}$$

$$V_o = -g_m V_{\pi} R_L' = -g_m \left( \frac{V_{sig2}}{sC_{in} R_{sig2} + 1} \right) R_L'$$

$$= -g_m \left( \frac{V_{sig2} V_{\pi}}{R_{sig2} + r_x + r_{\pi}} \right) \frac{R_L'}{(sC_{in} R_{sig2} + 1)}$$

$$V_o = -g_m \left( \frac{V_{sig} R_B}{R_{sig} + R_B} \right) \frac{V_{\pi}}{(R_{sig} + r_x + r_{\pi})} \left( \frac{R_L'}{sC_{in} R_{sig2} + 1} \right)$$

$$G_{rain} = \frac{V_o}{V_{sig}} = \left[ \frac{-g_m R_B V_{\pi} R_L'}{(R_{sig} + R_B)(R_{sig} + r_x + r_{\pi})} \right] \frac{1}{(sC_{in} R_{sig2} + 1)}$$

$$G_{rain} = \frac{A_{M}}{(sC_{in} R_{sig2} + 1)}$$

\* Product of gain & band width is = to const.

1/20/19

$$s = j\omega$$

$$\omega = \omega_H$$

$$|G_{\text{gain}}| = \frac{A_M}{\sqrt{2}}$$

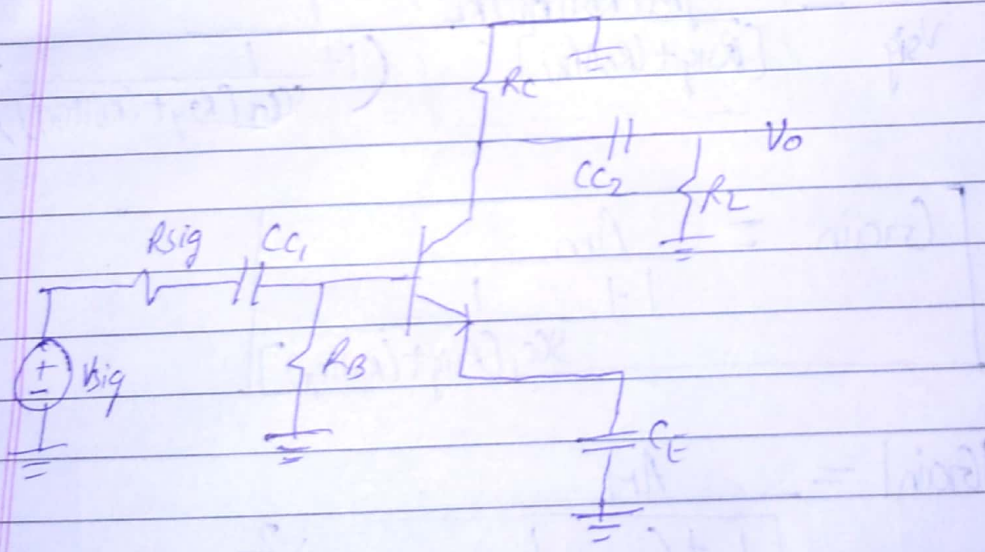
$$|G_{\text{gain}}| = \frac{A_M}{\sqrt{1 + (\omega C_{in} R_{\text{sig}2})^2}}$$

$$\frac{A_M}{\sqrt{2}} = \frac{A_M}{\sqrt{1 + (\omega_H C_{in} R_{\text{sig}2})^2}}$$

$$1 + (\omega_H C_{in} R_{\text{sig}2})^2 = 2$$

$$\omega_H = \frac{1}{C_{in} R_{\text{sig}2}}$$

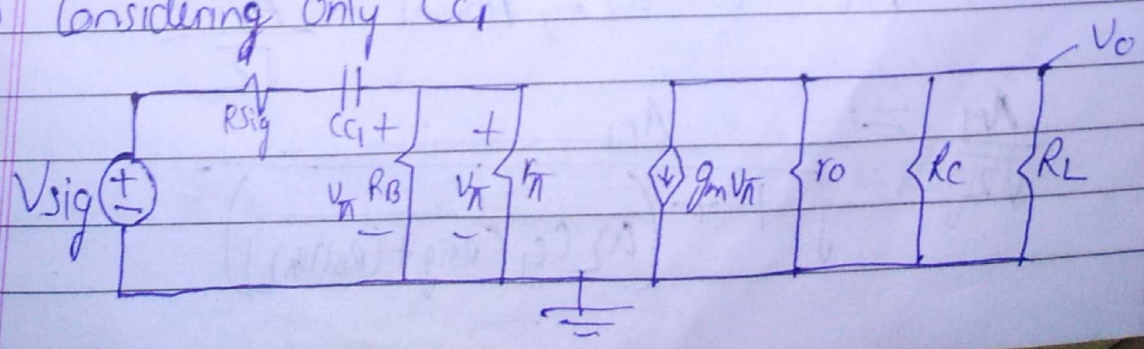
$$f_H = \frac{1}{2\pi C_{in} R_{\text{sig}2}}$$

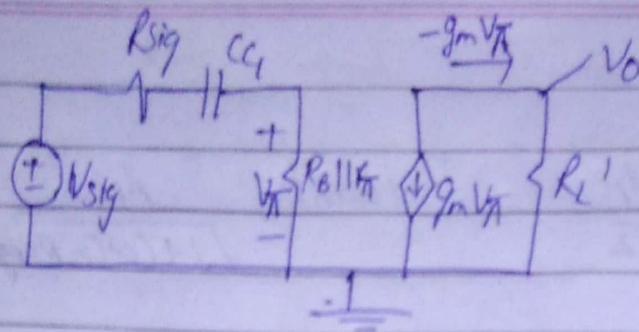


Low Freq. Analysis

① Considering only  $C_{c1}$

Apply  
Superposition  
Theorem





$$R_L' = R_{O1} \parallel R_{C1} \parallel R_L$$

$$V_o = -g_m V_{\pi} R_L'$$

$$V_{\pi} = \frac{V_{sig} (R_{B1} \parallel R_{B2})}{R_{sig} + \frac{1}{sC_{c1}} + (R_{B1} \parallel R_{B2})}$$

$$V_o = \frac{-g_m V_{sig} (R_{B1} \parallel R_{B2}) R_L'}{R_{sig} + \frac{1}{sC_{c1}} + (R_{B1} \parallel R_{B2})}$$

$$\text{Gain} = \frac{V_o}{V_{sig}} = \frac{-g_m (R_{B1} \parallel R_{B2}) R_L'}{[R_{sig} + (R_{B1} \parallel R_{B2})]} \left( 1 + \frac{1}{sC_{c1} [R_{sig} + (R_{B1} \parallel R_{B2})]} \right)$$

$$\boxed{\text{Gain} = \frac{A_m}{1 + \frac{1}{sC_{c1} [R_{sig} + (R_{B1} \parallel R_{B2})]}}}$$

$$|\text{Gain}| = \frac{A_m}{\sqrt{1 + \left( \frac{1}{\omega C_{c1} [R_{sig} + (R_{B1} \parallel R_{B2})]} \right)^2}}$$

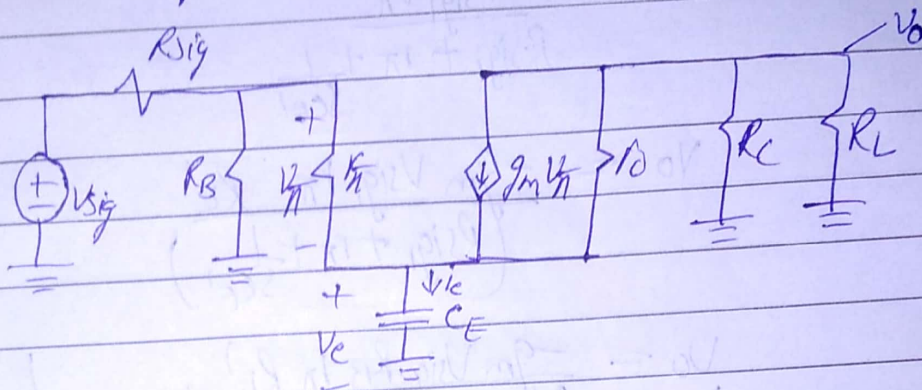
$$\text{At } \omega = \omega_c, |\text{Gain}| = \frac{A_m}{\sqrt{2}}$$

$$\frac{A_m}{\sqrt{2}} = \frac{A_m}{\sqrt{1 + \left( \frac{1}{\omega_c C_{c1} [R_{sig} + (R_{B1} \parallel R_{B2})]} \right)^2}}$$

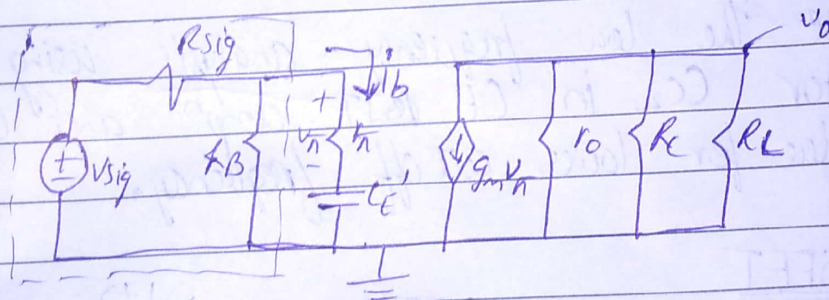
$$\omega_{L1} = \frac{1}{C_{C1} [R_{sig} + (R_B || r_{\pi})]}$$

$$\text{Gain} = \frac{A_M}{1 + \frac{\omega_{L1}}{j\omega}}$$

(2) Considering only CE



$$v_e = \frac{i_e}{s C_E}$$

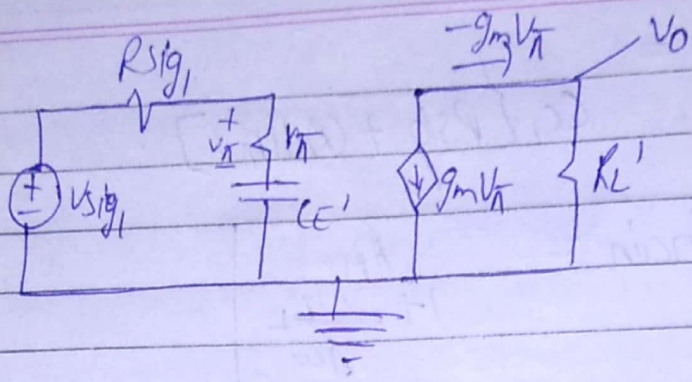


$$i_{b1} = \frac{i_e}{\beta + 1}$$

$$i_b = \frac{i_b1}{C_E'}$$

$$C_E' = \frac{C_E}{1 + \beta}$$

$$v_{sig1} = \frac{v_{sig} R_B}{R_{sig} + R_B}, \quad R_{sig1} = R_{sig} || R_B$$



$$V_o = -g_m V_{\pi} R_L'$$

$$V_{\pi} = \frac{V_{sig1} r_{\pi}}{R_{sig1} + r_{\pi} + \frac{1}{s C_{E'}}$$

$$V_o = \frac{-g_m V_{sig1} r_{\pi} R_L'}{\left( R_{sig1} + r_{\pi} + \frac{1}{s C_{E'}} \right)}$$

$$V_o = \frac{-g_m V_{sig} R_B r_{\pi} R_L'}{(R_{sig} + R_B)(R_{sig1} + r_{\pi})} \left( 1 + \frac{1}{s C_{E'}(R_{sig1} + r_{\pi})} \right)$$

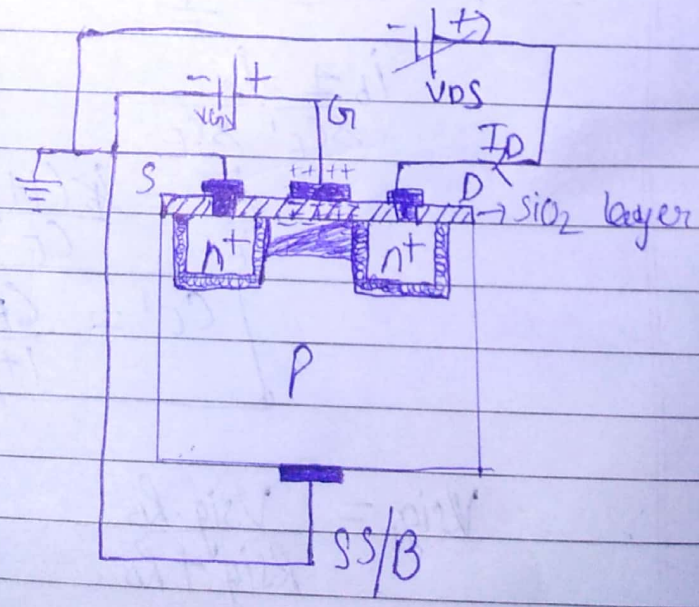
24/10/19

Assignment

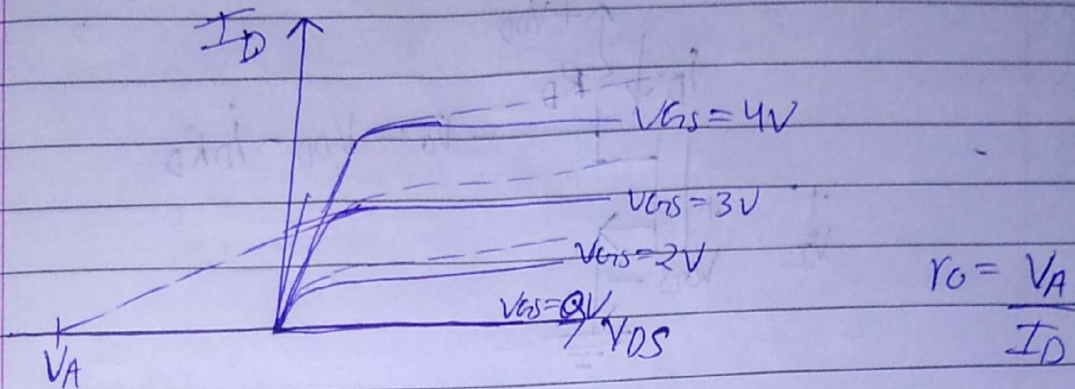
Q Analyse the low frequency analysis using Capacitor  $C_{C2}$  in CE BJT amp<sup>n</sup> and Calculate the value for lower cut off frequency.

MOSFET

① E-MOSFET

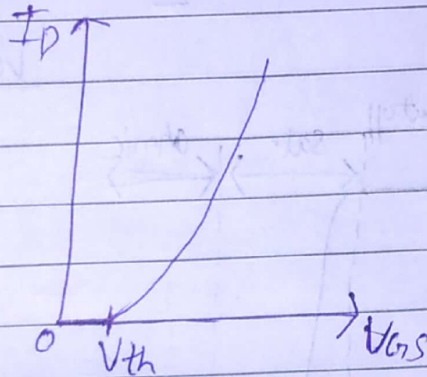


## Drain Characteristics



$$r_o = \frac{V_A}{I_D}$$

## Transfer Characteristics



15/10/19

$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{GS} - V_{th})^2 \quad \left[ \begin{array}{l} \text{valid} \\ \text{for saturation region} \end{array} \right]$$

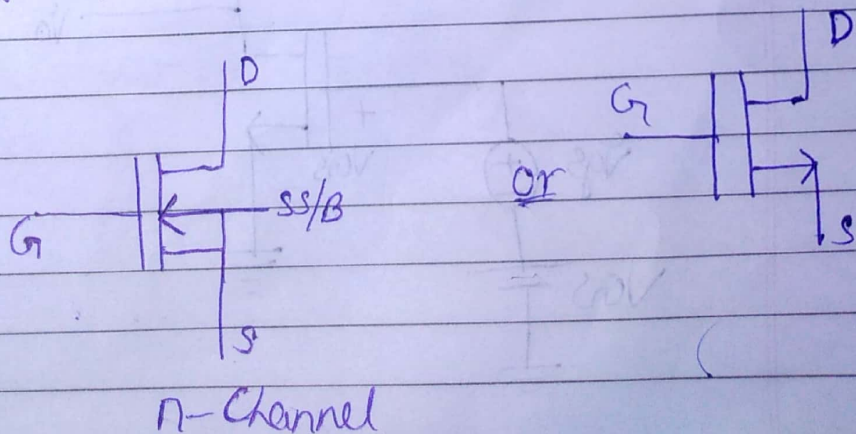
$\mu_n$  = mobility of electron

$C_{ox}$  = oxide capacitance per unit area

$W$  = width of the channel  $\text{SiO}_2$  layer

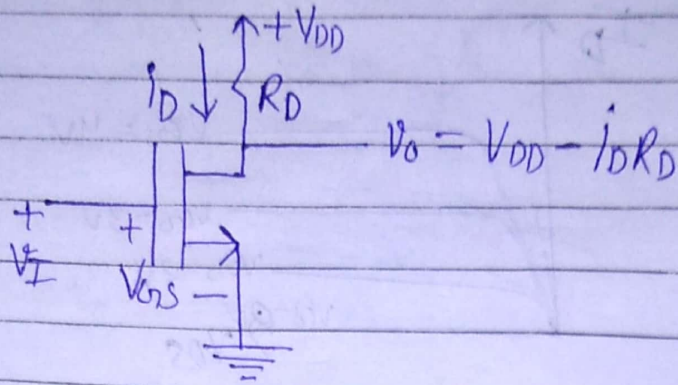
$L$  = length of the channel

## Symbol



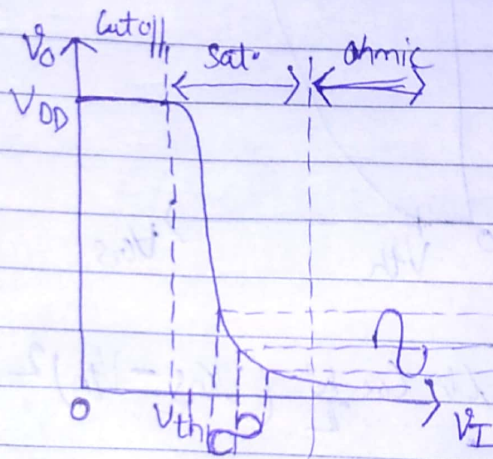


# MOSFET as an Amp<sup>n</sup> & as a switch

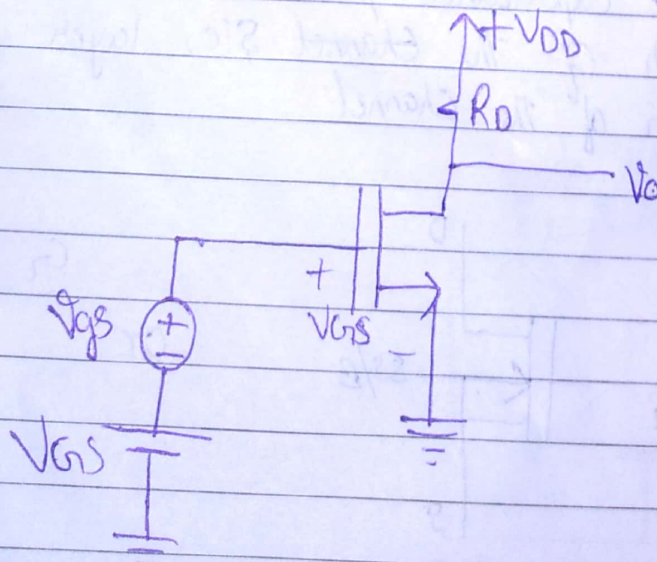


$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{GS} - V_{th})^2$$

$$V_{GS} \geq V_{th}$$



## Small Signal op<sup>n</sup> & Model



$$g_m = \frac{i_D}{v_{gs}}$$

$$i_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{ovs} - V_{th})^2$$

$$i_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (v_{gs} + V_{ovs} - V_{th})^2$$

$$i_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \underbrace{v_{gs}^2}_{\substack{\text{Very-very} \\ \text{small}}} + \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{ovs} - V_{th})^2 + \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \times 2 v_{gs} (V_{ovs} - V_{th})$$

$$i_D = \underbrace{\frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{ovs} - V_{th})^2}_{\substack{\downarrow \text{DC} \\ I_D}} + \underbrace{\mu_n C_{ox} \frac{W}{L} v_{gs} (V_{ovs} - V_{th})}_{\text{ac}}$$

$$i_{d,ac} = \mu_n C_{ox} \frac{W}{L} v_{gs} (V_{ovs} - V_{th})$$

$$g_m = \frac{i_{d,ac}}{v_{gs}} = \mu_n C_{ox} \frac{W}{L} (V_{ovs} - V_{th})$$

$$g_m = K_n' \frac{W}{L} V_{ov}$$

$$V_{ov} = V_{ovs} - V_{th} = \text{overdrive voltage}$$

16/10/19

$$V_o = V_{DD} - i_D R_D$$

ac+dc

$$= V_{DD} - \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{GS} - V_{th})^2 R_D$$

$$= V_{DD} - \frac{1}{2} \frac{kn'W}{L} \left[ \underbrace{V_{GS}}_a + \underbrace{V_{GS} - V_{th}}_b \right]^2 R_D$$

$$= V_{DD} - \frac{1}{2} \frac{kn'W}{L} V_{GS}^2 - \frac{1}{2} \frac{kn'W}{L} (V_{GS} - V_{th})^2 R_D - \frac{1}{2} \frac{kn'W}{L} 2 V_{GS} (V_{GS} - V_{th}) R_D$$

Small

$$V_o = V_{DD} - \frac{1}{2} \frac{kn'W}{L} (V_{GS} - V_{th})^2 R_D - kn' \frac{W}{L} V_{GS} (V_{GS} - V_{th}) R_D$$

ac+dc

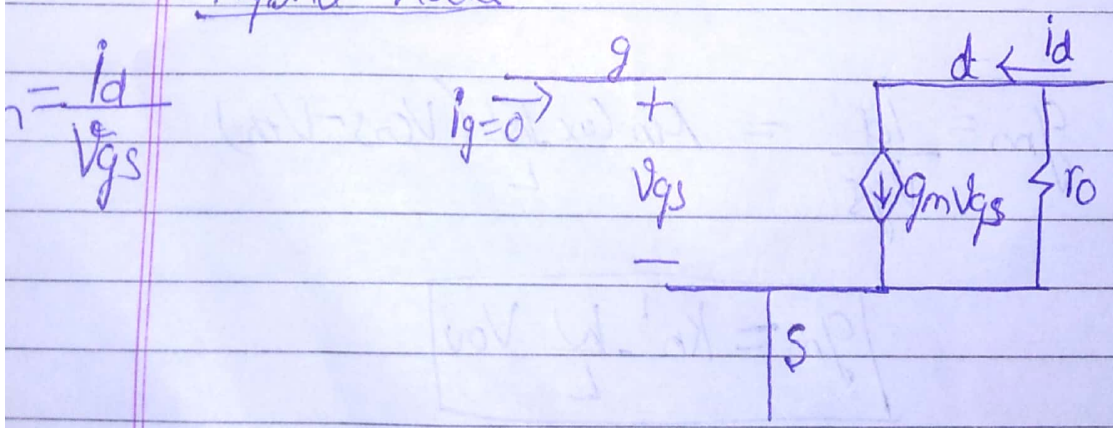
$$V_o = -kn' \frac{W}{L} V_{GS} (V_{GS} - V_{th}) R_D$$

ac

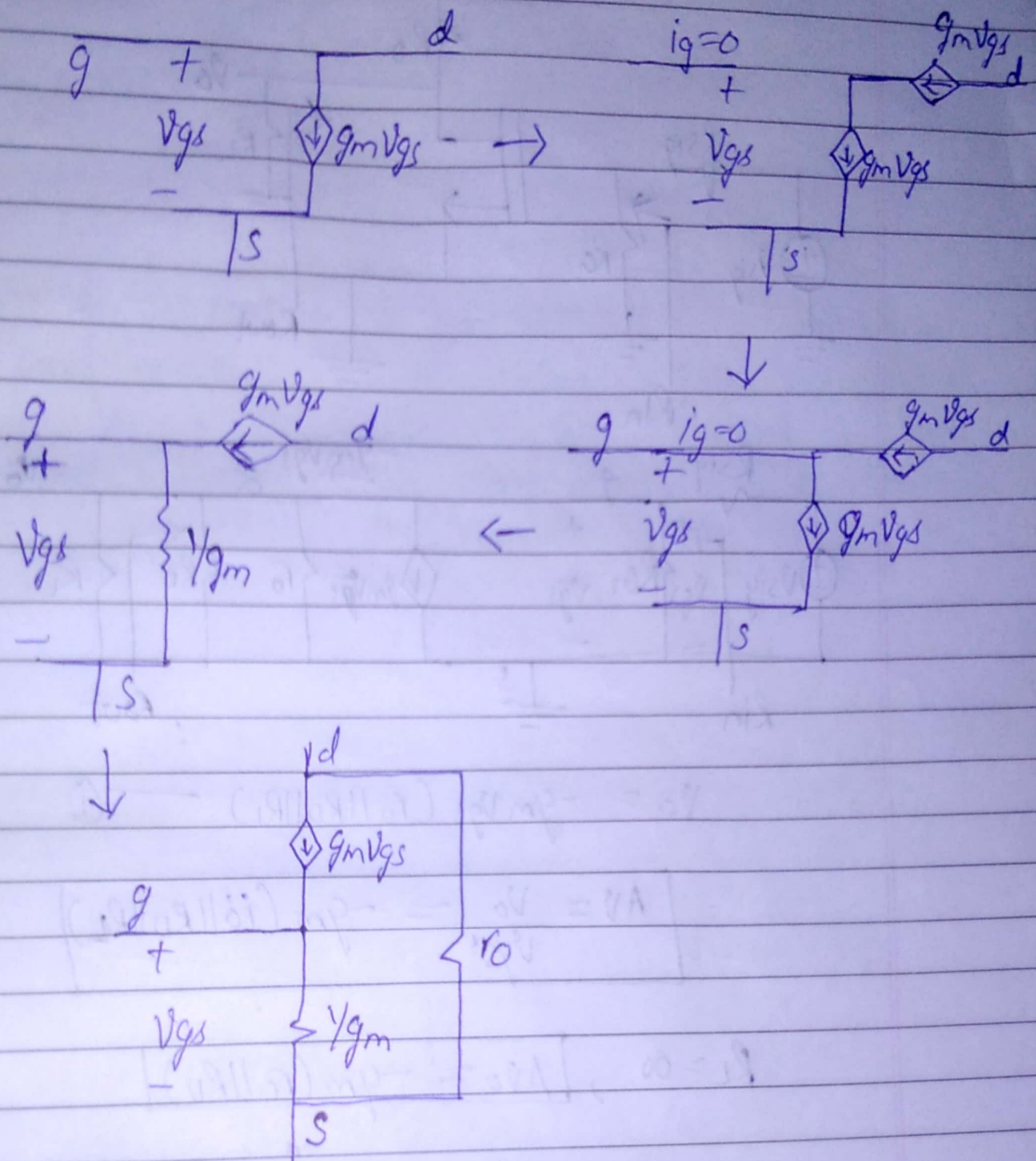
$$Gain = \frac{V_o(ac)}{V_{GS}} = -kn' \frac{W}{L} (V_{GS} - V_{th}) R_D$$

$$Gain = -g_m R_D$$

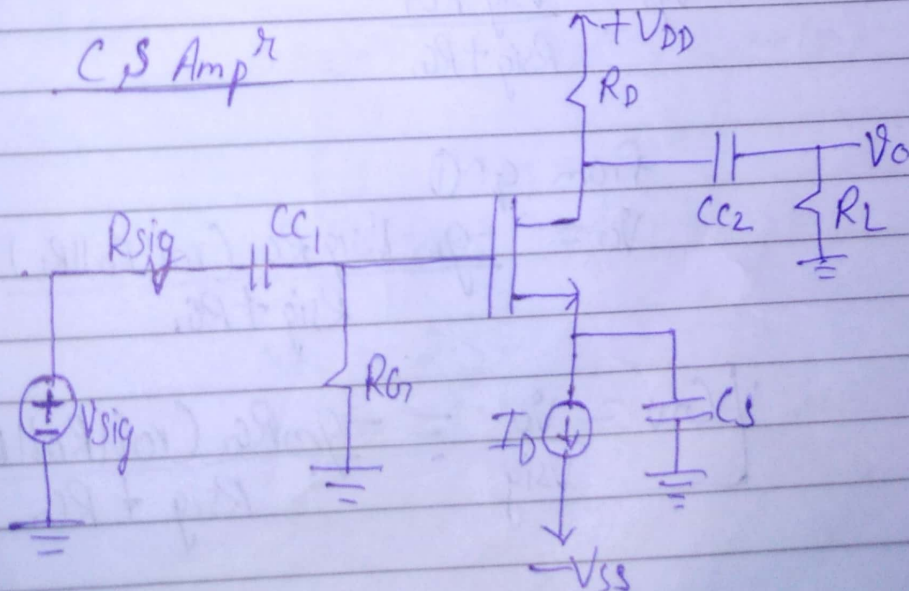
Hybrid Model

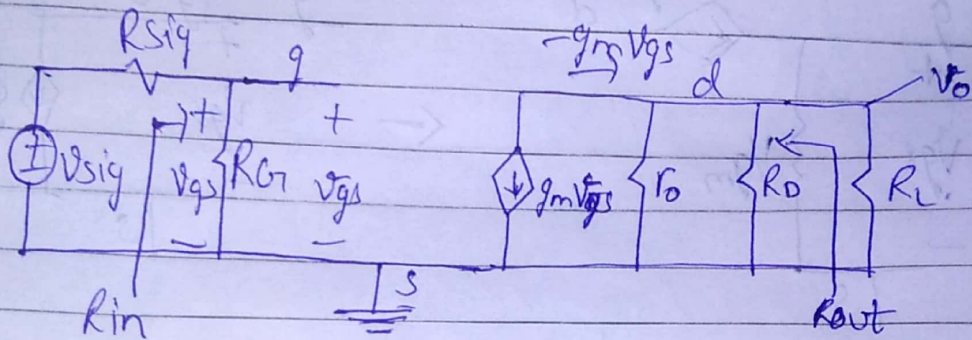
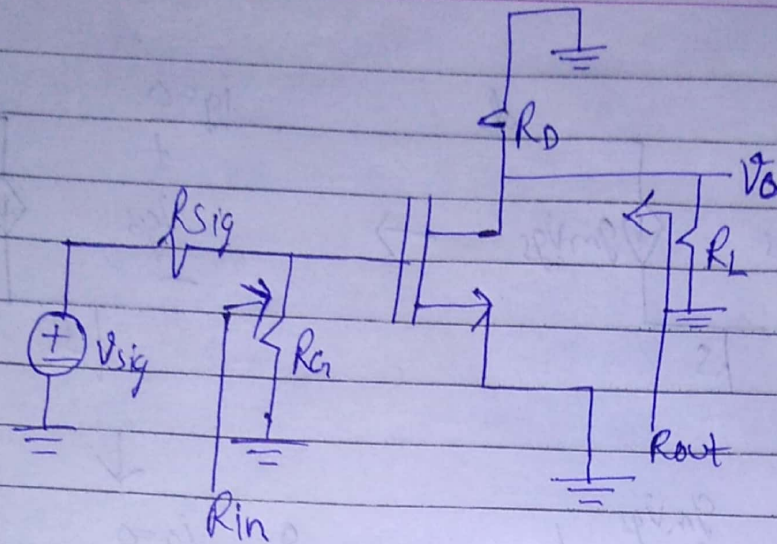


T-Model



CS Amp<sup>er</sup>





$$V_o = -g_m V_{gs} (r_o \parallel R_o \parallel R_L) \quad \text{--- (1)}$$

$$A_V = \frac{V_o}{V_{gs}} = -g_m (r_o \parallel R_o \parallel R_L)$$

$$R_L = \infty, \quad A_{V0} = -g_m (r_o \parallel R_o)$$

$$V_{gs} = \frac{V_{sig} R_{G1}}{R_{sig} + R_{G1}}$$

from eq<sup>n</sup> (1)

$$V_o = \frac{-g_m V_{sig} R_{G1} (r_o \parallel R_o \parallel R_L)}{R_{sig} + R_{G1}}$$

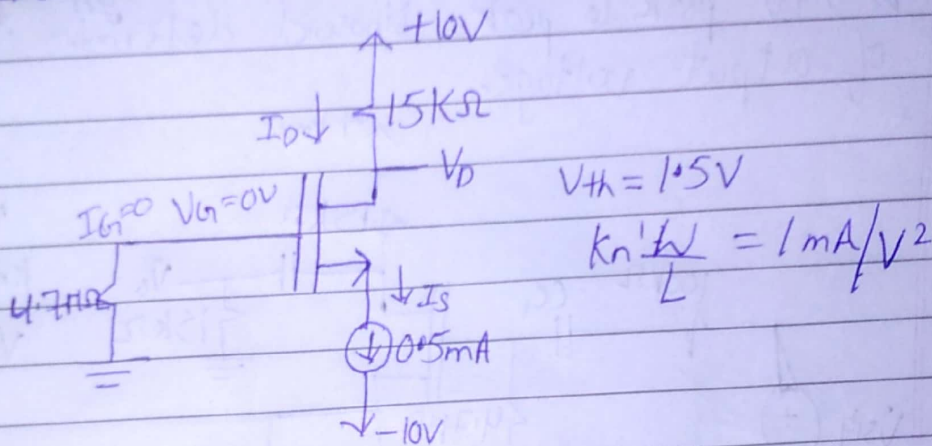
$$G_{V0} = \frac{V_o}{V_{sig}} = \frac{-g_m R_{G1} (r_o \parallel R_o \parallel R_L)}{R_{sig} + R_{G1}}$$

$$R_L = \infty, \quad G_{vo} = \frac{-g_m R_G (r_o \parallel R_D)}{R_{sig} + R_G}$$

$$R_{in} = R_G$$

$$R_{out} = r_o \parallel R_D$$

17/10/19 For the circuit shown in fig. determine  $V_{ov}$ ,  $V_{gs}$ ,  $V_{gs}$ ,  $V_s$  and  $V_D$ . Also calculate the value of  $g_m$  and  $r_o$  if  $V_A = 75V$ . What is the maximum possible signal swing at the drain terminal for which the MOSFET remains in saturation region.



Sol

$$V_{ov} = V_{gs} - V_{th}$$

$$I_D = \frac{1}{2} k_n' \frac{W}{L} (V_{gs} - V_{th})^2$$

$$0.5 \times 10^{-3} = \frac{1}{2} \times 10^{-3} (V_{gs} - 1.5)^2$$

$$1 = (V_{gs} - 1.5)^2$$

$$V_{gs} = 2.5V, 0.5V$$

$$V_{ov} = 2.5 - 1.5$$

$$V_{ov} = 1V$$

$$V_{G1} = 0V$$

$$V_{gs} = V_{G1} - V_s$$

$$V_s = -V_{gs}$$

$$V_s = -2.5V$$

$$V_D = 10 - (15 \times 10^3 \times 0.5 \times 10^{-3})$$

$$V_D = 2.5V$$

$$V_{DS} = V_D - V_S$$

$$= 2.5 - (-2.5)$$

$V_{DS} > (V_{GS} - V_{th})$  Saturation  
 $V_{DS} < (V_{GS} - V_{th})$  Ohmic

$$V_{DS} = 5V$$

Saturation Region

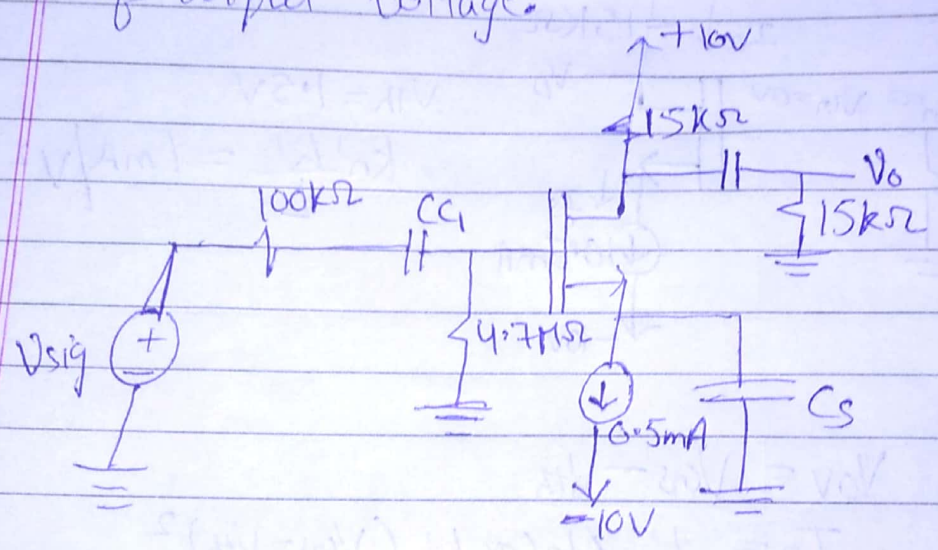
$$g_m = k_n' \frac{W}{L} (V_{GS} - V_{th})$$

$$= 10^{-3} \times 1 = 1ms$$

$$V_{Dmax} = 10V$$

$$r_o = \frac{V_A}{I_D} = 150k\Omega$$

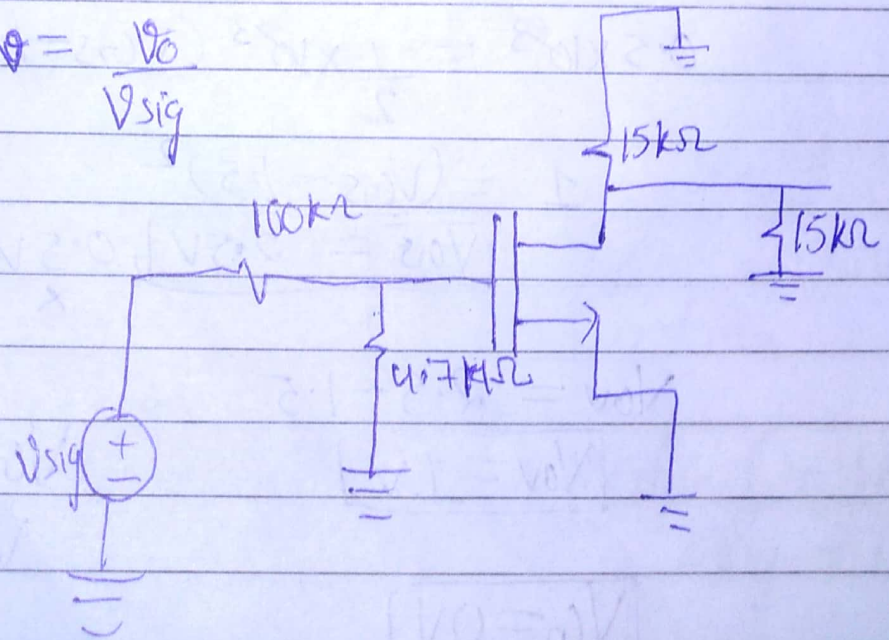
Q For the ckt shown in fig. determine  $G_{TV}$ . If  $V_{sig}$  is 0.4V peak to peak sinusoid determine the value of output voltage.

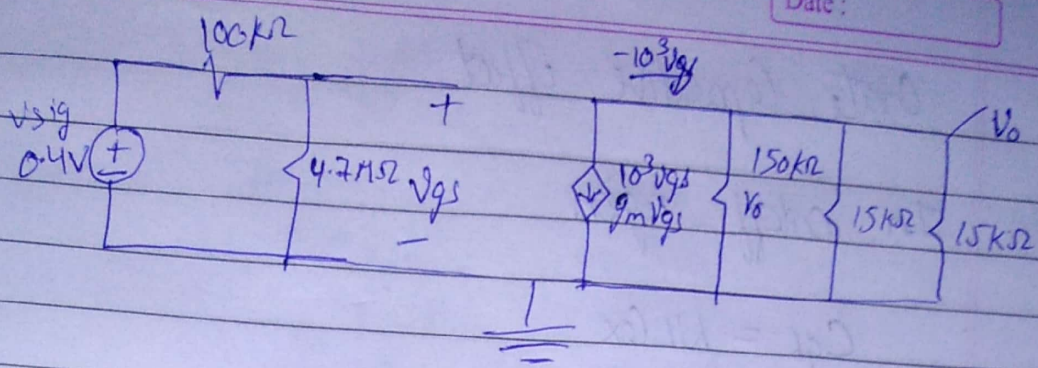


$V_A = 75V$   
 $k_n' \frac{W}{L} = 1mA/V^2$   
 $V_{th} = 1.5V$

Sol

$$G_{TV} = \frac{V_o}{V_{sig}}$$





$$V_o = -10^{-3} V_{gs} (150k \parallel 15k \parallel 15k)$$

$$V_{gs} = \frac{V_{sig} \times 4.7 \times 10^6}{100 \times 10^3 + 4.7 \times 10^6}$$

$$G_{v} = \frac{V_o}{V_{sig}}$$

$$V_{gs} = \frac{0.4 \times 4.7 \times 10^6}{10^3 [100 + 4700]}$$

$$G_{v} = -10^{-3} (150k \parallel 15k \parallel 15k) \times \frac{4.7 \times 10^6}{(100 \times 10^3 + 4.7 \times 10^6)}$$

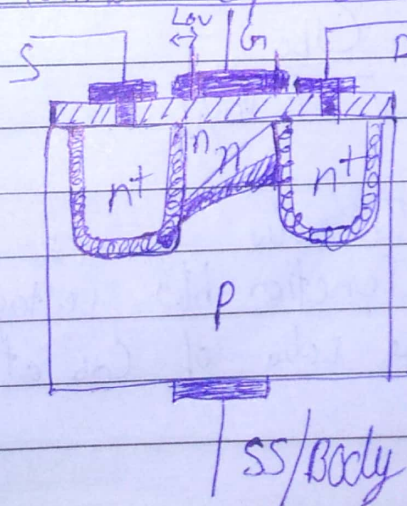
$$= -6.99 \text{ V/V}$$

$$V_{sig} = 0.4 \text{ V}_{pp}$$

$$V_o = G_v V_{sig} = -6.99 \times 0.4 \text{ V}_{pp}$$

$$= -2.76 \text{ V}_{pp}$$

### 3/10/19 MOSFET Internal Capacitances



- $C_{ox}$
- $C_{gb}$
- $C_{gs}$
- $C_{gd}$
- $C_{sb}$
- $C_{db}$



$C_{ov}$  = overlap capacitance

Page No.

Date:

## Gate Capacitive Effect

(i) In cutoff region

$$C_{gb} = WL C_{ox}$$

$$C_{gs} = C_{gd} = 0$$

(ii) In Ohmic region

$$C_{gb} = 0$$

$$C_{gs} = C_{gd} = \frac{1}{2} WL C_{ox}$$

(iii) In saturation region

$$C_{gd} = 0$$

$$C_{gs} = \frac{2}{3} WL C_{ox}$$

overlap capacitance

$$C_{ov} = WL_{ov} C_{ox}$$

## Body Capacitance

$$C_{sb} = \frac{C_{sbo}}{\sqrt{1 + V_{sb}/V_0}}$$

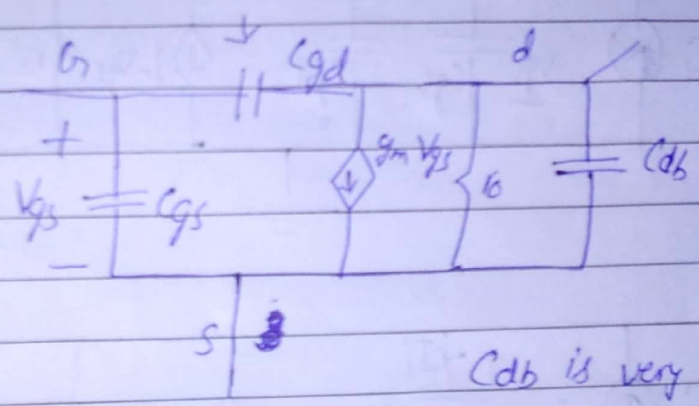
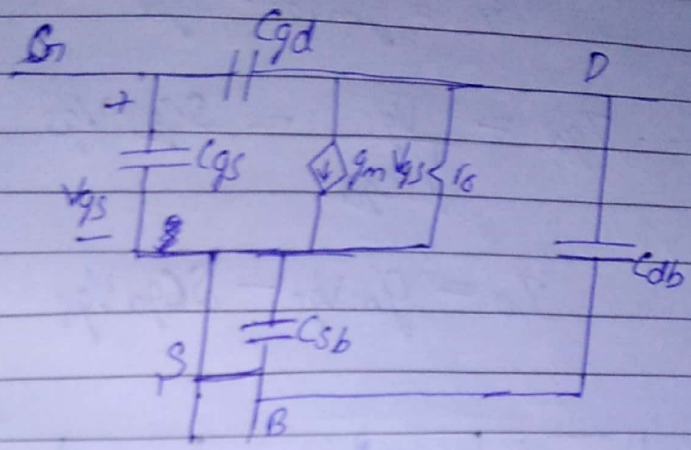
$$C_{db} = \frac{C_{dbo}}{\sqrt{1 + V_{db}/V_0}}$$

where  $C_{sbo}$  = The value of  $C_{sb}$  at  $V_{sb} = 0$

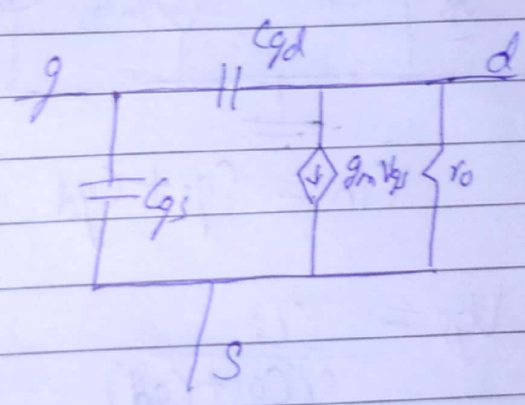
$V_0$  = Junction bias voltage

$C_{dbo}$  = The value of  $C_{db}$  at  $V_{db} = 0$

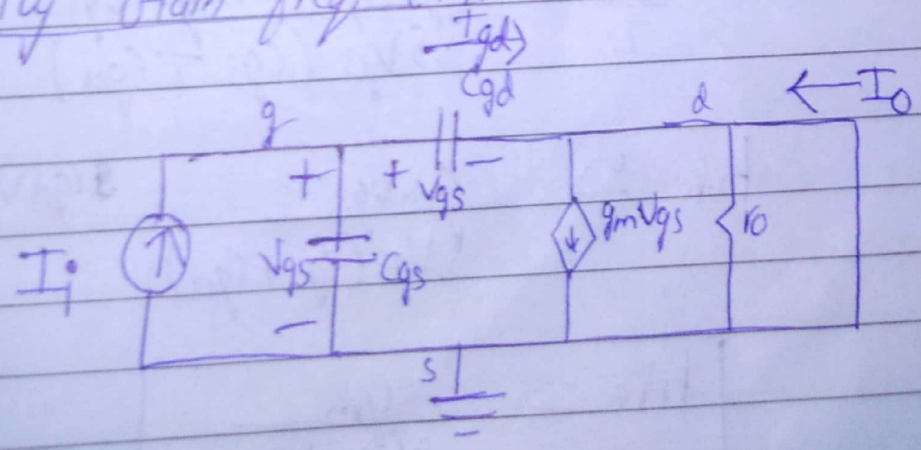
# High Frequency Model



$C_{db}$  is very very small



## Unity Gain freq: (fT)

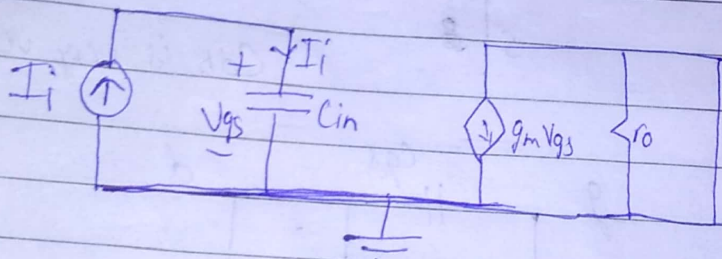
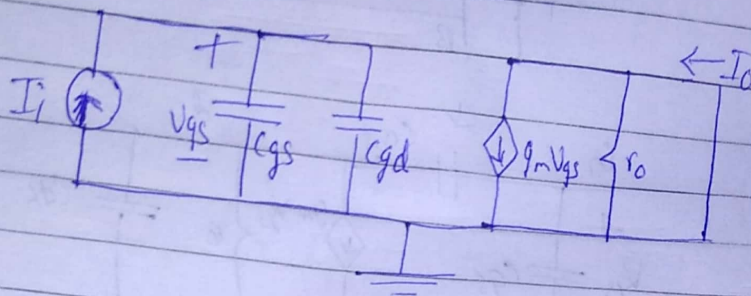


$$I_{gd} + I_o = g_m V_{gs}$$

$$I_o = g_m V_{gs} - I_{gd}$$

$$I_{gd} = \frac{V_{gs}}{1/sC_{gd}} = sC_{gd} V_{gs}$$

$$I_o = g_m V_{gs} - sC_{gd} V_{gs}$$



$$C_{in} = C_{gs} + C_{gd}$$

$$I_i = V_{gs} s(C_{gs} + C_{gd})$$

$$V_{gs} = \frac{I_i}{s(C_{gs} + C_{gd})}$$

$$h_{fe} = \frac{I_o}{I_i} = \frac{g_m V_{gs} - sC_{gd} V_{gs}}{s V_{gs} (C_{gs} + C_{gd})}$$

$$h_{fe} \approx \frac{g_m V_{gs}}{s V_{gs} (C_{gs} + C_{gd})} \quad sC_{gd} V_{gs} \ll g_m V_{gs}$$

$$h_{fe} = \frac{g_m}{s(C_{gs} + C_{gd})}$$

$$t_{4e} = \frac{g_m}{\omega (C_{gs} + C_{gd})}$$

$$|H_{fe}| = \frac{g_m}{\omega (C_{gs} + C_{gd})}$$

$$\text{At } \omega = \omega_T, |H_{fe}| = 1$$

$$1 = \frac{g_m}{\omega_T (C_{gs} + C_{gd})}$$

$$\Rightarrow \omega_T = \frac{g_m}{C_{gs} + C_{gd}}$$

unity gain frequency.

Q Determine  $C_{de}$ ,  $C_{je}$ ,  $C_T$ ,  $C_u$ ,  $f_T$  for a BJT operating at  $I_C = 1\text{mA}$  and CBJ reverse bias of  $2\text{V}$ . The device has  $f_T = 20\text{ps}$ ,  $C_{je0} = 20\text{fF}$ ,  $C_{u0} = 20\text{fF}$ ,  $V_{be} = 0.9\text{V}$ ,  $V_{bc} = 0.5\text{V}$  and  $M_{CBT} = 0.33$ . Also draw the high freq. model indicating all the values. Given that  $V_A = 100\text{V}$ ,  $\beta = 100$ .

Sol (i)  $C_{de} = \frac{f_T g_m}{V_T} = \frac{f_T I_C}{V_T}$

$$= \frac{20 \times 10^{-12} \times 10^{-3}}{25 \times 10^{-3}}$$

$$= 0.8 \times 10^{-12} \text{ F}$$

$$= 0.8 \text{ pF}$$

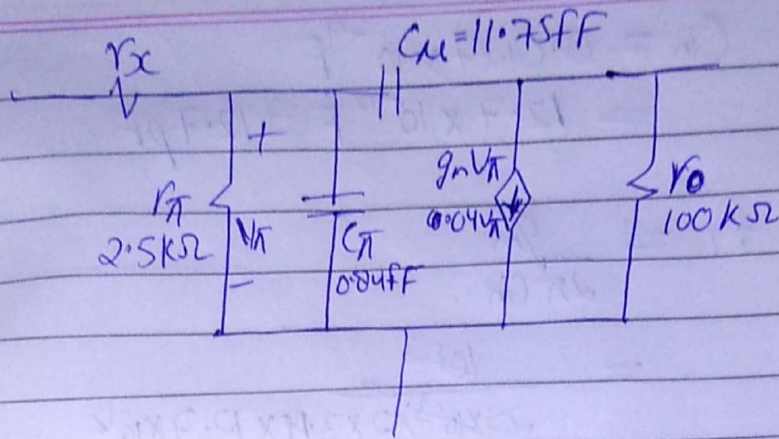
(ii)  $C_{je} = \frac{C_{je0}}{(1 - V_{BE}/V_{be})^m} \approx 2 C_{je0}$

$$C_{je} = 40 \text{ fF}$$

$$\begin{aligned}
 \text{(ii)} \quad C_T &= C_{de} + C_{je} \\
 &= 0.8 \times 10^{-12} + 40 \times 10^{-15} \\
 &= 0.84 \times 10^{-12} \text{ F} \\
 &= 0.84 \text{ pF}
 \end{aligned}$$

$$\begin{aligned}
 \text{(iv)} \quad C_{ae} &= \frac{C_{MO}}{\left(1 + \frac{V_{CB}}{V_{OC}}\right)^m} \\
 &= \frac{20}{\left(1 + \frac{2}{0.5}\right)^{0.33}} \\
 &= \frac{20}{\left(\frac{2.5}{0.5}\right)^{0.33}} = \frac{20}{1.7} \\
 C_{ae} &= 11.76 \text{ fF}
 \end{aligned}$$

$$\begin{aligned}
 \text{(v)} \quad f_T = \omega_T &= \frac{\beta_0}{C_{in} f_T} = \frac{\beta_0}{(C_T + C_{ae}) \beta_0} = \frac{g_m}{C_T + C_{ae}} \\
 &= \frac{g_m}{2\pi (C_T + C_{ae})} = \frac{I_C}{2\pi V_T (C_T + C_{ae})} \\
 &= \frac{10^{-3}}{2\pi \times 25 \times 10^{-12} (0.84 \times 10^{-12} + 11.75 \times 10^{-15})} \\
 &= \frac{1}{2\pi \times 25 \times 10^{-12} \times 0.85175} \\
 &= 7.47 \times 10^9 \text{ Hz} \\
 \omega_T &= 7.47 \text{ GHz}
 \end{aligned}$$



$$r_{\pi} = \frac{\beta_0}{g_m} = \frac{100 \times 25 \times 10^{-3}}{10^{-3}} = 2.5 \text{ k}\Omega$$

$$g_m = \frac{I_C}{V_T} = \frac{10^{-3}}{25 \times 10^{-3}} = 0.04 \text{ S}$$

$$r_o = \frac{V_A}{I_C} = \frac{100}{10^{-3}} = 100 \text{ k}\Omega$$

Q Given that  $I_C = 1 \text{ mA}$ ,  $C_{\mu} = 2 \text{ pF}$  and  $|h_{fe}| = 10$  at  $50 \text{ MHz}$ . Determine  $f_T = ?$  and  $C_{\pi} = ?$

Sol  $f_T = \frac{g_m}{2\pi(C_{\mu} + C_{\pi})}$

$$|h_{fe}| = \frac{\beta_0}{\sqrt{(2\pi f C_{\pi} r_{\pi})^2 + 1}} = \frac{\beta_0}{\sqrt{(2\pi f C_{\pi} r_{\pi})^2 + 1}}$$

$$10 = \frac{\beta_0}{\sqrt{(2\pi \times 50 \times 10^6 C_{\pi} r_{\pi})^2 + 1}} \rightarrow \text{neglect because 2 unknown}$$

$$10 = \frac{\beta_0}{2\pi \times 50 \times 10^6 \times C_{\pi} \times \beta_0 / g_m}$$

$$C_{\pi} = \frac{g_m}{2\pi \times 50 \times 10^6 \times 10}$$

$$= \frac{10^{-3}}{2\pi \times 50 \times 10^6 \times 10 \times 25 \times 10^{-3}}$$

$$C_{in} = 0.0127 \times 10^{-9} F$$

$$= 12.7 \times 10^{-12} F = 12.7 pF$$

$$f_T = \frac{g_m}{2\pi C_{in}}$$

$$= \frac{10^{-3}}{25 \times 10^{-3} \times 2 \times 3.14 \times 12.7 \times 10^{-12}}$$

$$= 501 \times 10^6 \text{ Hz}$$

$$f_T = 501 \text{ MHz}$$

$$C_{in} = C_u + C_{\pi}$$

$$12.7 pF = C_{\pi} + 2 pF$$

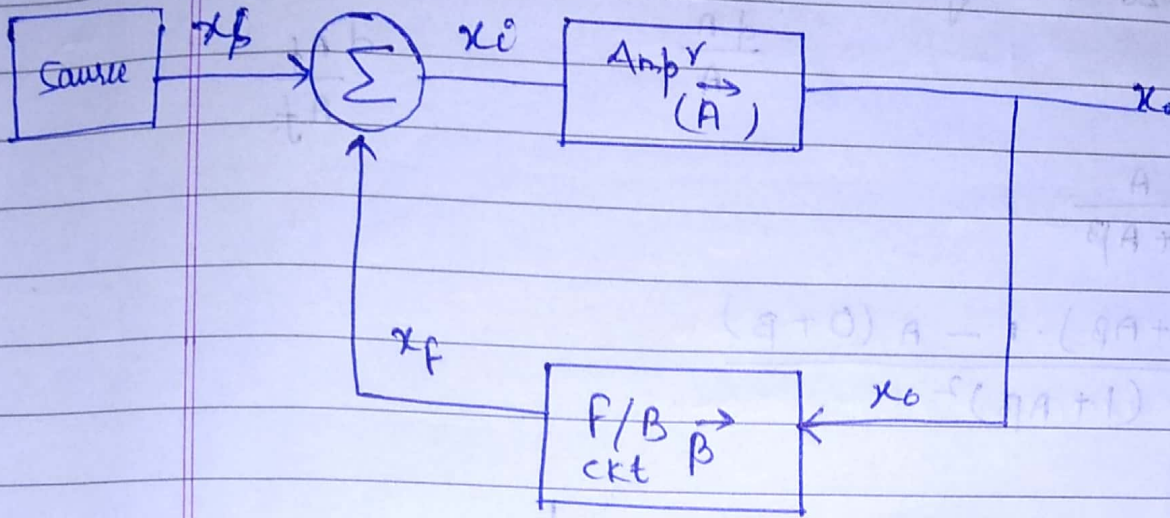
$$C_{\pi} = 10.7 pF$$

# Second PDF



General feedback structure:-

# Desensitize the gain



$$x_i = x_s - x_f$$

$$A = \frac{x_o}{x_i}$$

$$\beta = \frac{x_f}{x_o}$$

$$A_f = \frac{x_o}{x_s} = \frac{x_o}{x_i + x_f}$$

$$A_f = \frac{x_o}{x_s}$$

$$= \frac{x_o/x_i}{1 + \frac{x_f}{x_i}}$$

$$= \frac{x_o/x_i}{1 + \frac{x_o}{x_i} \beta}$$

$$A_f = \frac{A}{1 + A\beta}$$

$$A_f < A$$

- Properties of Negative feedback.

1. Densensitize the gain:-

$$A_f = \frac{A}{1+AB}$$

$$\frac{dA_f}{dA} = \frac{(1+AB) \cdot 1 - A(0+B)}{(1+AB)^2}$$

$$\frac{dA_f}{dA} = \frac{1+AB-AB}{(1+AB)^2} = \frac{1}{(1+AB)^2}$$

$$dA_f = \frac{dA}{(1+AB)^2}$$

$$\frac{dA_f}{A_f} = \frac{dA}{(1+AB)^2 A_f}$$

$$\frac{dA_f}{A_f} = \frac{dA}{(1+AB)^2} \cdot \frac{A}{1+AB}$$

$$\frac{dA_f}{A_f} = \frac{1}{(1+AB)} \cdot \frac{dA}{A}$$

- 2. Increase the bandwidth

$$B.W = f_H - f_L$$

$$= f_{Hf} - f_{Lf}$$

$$f_{Hf} > f_H$$

$$f_{Lf} < f_L$$

High frequency Response

$$A = \frac{A_m}{1 + \frac{s}{\omega_H}}$$

$$A_f = \frac{A}{1 + A\beta}$$

$$= \frac{A_m}{\frac{(1 + s/\omega_H)}{1 + A_m\beta}}$$

$$A_f = \frac{A_m}{1 + s/\omega_H + A_m\beta}$$

$$= \frac{A_m}{(1 + A_m\beta) + s/\omega_H}$$

$$A_f = \frac{A_m / (1 + A_m\beta)}{1 + \frac{s}{\omega_H(1 + A_m\beta)}} \quad \text{--- (1)}$$

$$A_f = \frac{A_{mf}}{1 + \frac{s}{\omega_{Hf}}} \quad \text{--- (2)}$$

$$A_{mf} = \frac{A_m}{(1 + A_m \beta)}$$

$$\omega_{Hf} = \omega_H (1 + A_m \beta)$$

$$\omega_{Hf} > \omega_H$$

• Low frequency Response:-

$$A = \frac{A_m}{1 + \frac{\omega_L}{s}}$$

$$A_f = \frac{A}{1 + A\beta}$$

$$A_f = \frac{A_m}{1 + \frac{\omega_L}{s}} \cdot \frac{1}{1 + A_m \beta \left(1 + \frac{\omega_L}{s}\right)}$$

$$A_f = \frac{A_m}{1 + \frac{\omega_L}{s} + A_m \beta}$$

$$= \frac{A_m / (1 + A_m \beta)}{1 + \frac{\omega_L}{s(1 + A_m \beta)}}$$

$$A_f = \frac{A_{mf}}{1 + \frac{\omega L_f}{s}}$$

$$A_{mf} = \frac{A_m}{1 + A_m \beta}$$

$$\omega_{Lf} = \frac{\omega_L}{(1 + A_m \beta)}$$

$$\omega_{Lf} < \omega_L$$

③ Reduce the non linear Distortion:

$$V_o = A (V_{in} + V_{in}^2 + V_{in}^3) \dots \dots \dots$$

$$= A V_{in} + A V_{in}^2 + A V_{in}^3$$

$$V_{of} = A_f (V_{in} + V_{in}^2 + V_{in}^3)$$

$$= A_f V_{in} + A_f V_{in}^2 + A_f V_{in}^3$$

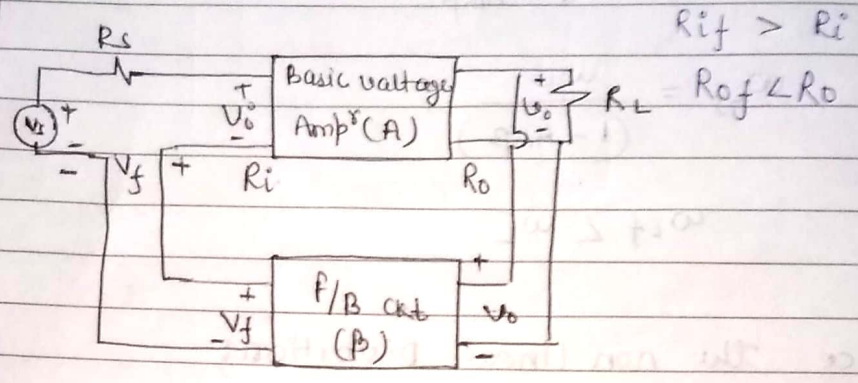
As  $A_f < A$  so  $V_{of} < V_o$  non linear distortion,

• Various type of

• Basic Topologies:-

- ① • Voltage amplifier

$$V_i = V_s - V_f$$

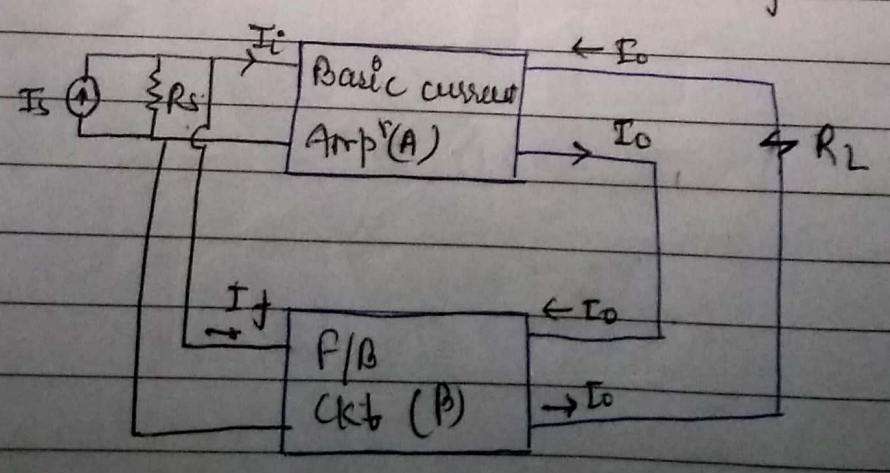


Other name  $\rightarrow$  series shunt F/B Amp<sup>r</sup>  
 Voltage sampling voltage mixing Amp<sup>r</sup>  
 Voltage series F/B  
 o/p sample      i/p side

- ② • Current amplifiers:-

$$R_{if} < R_i$$

$$R_{of} > R_o$$

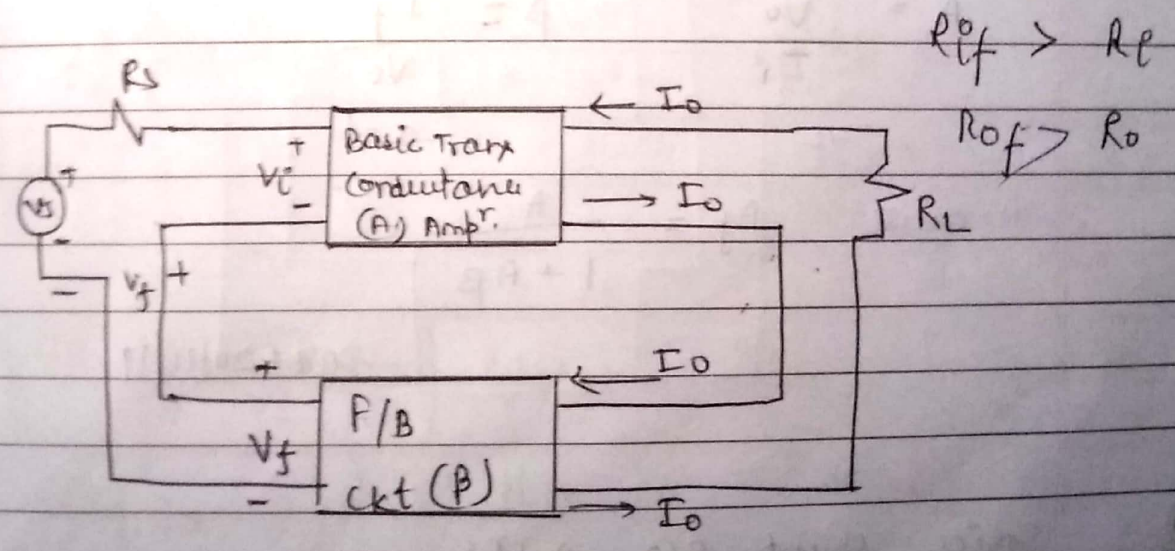


$$A = \frac{I_o}{I_i}$$

$$\beta = \frac{I_f}{I_o}$$

Other name - shunt series F/B Amp<sup>r</sup>.  
 Current sampling Current mixing Amp<sup>r</sup>,  
 Current shunt F/B  
 O/P sample i/P shunt

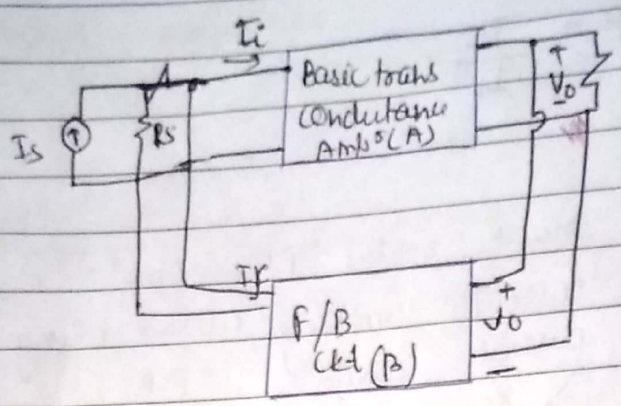
③ Transconductance Amp<sup>r</sup>



Other name series series F/B Amp<sup>r</sup>  
 Current sampling Voltage mixing Amp<sup>r</sup>  
 Current series F/B

④ TRANS RESISTANCE Amp<sup>r</sup>

$R_i \ll R_s$   
 $R_o \ll R_L$



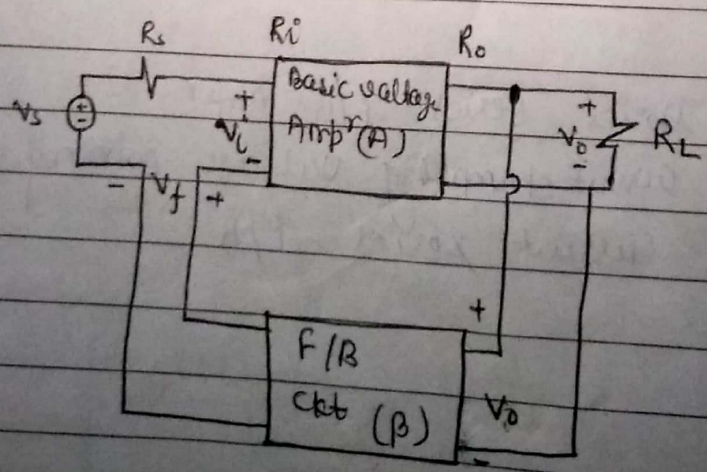
Other name :-  
shunt shunt F/B Amp<sup>r</sup>  
Voltage Sampling Current mixing Amp<sup>r</sup>  
Voltage ~~Current~~ shunt F/B

$$A = \frac{V_o}{I_i} \quad \beta = \frac{I_f}{V_o}$$

Because  $A_f = \frac{A}{1 + A\beta}$

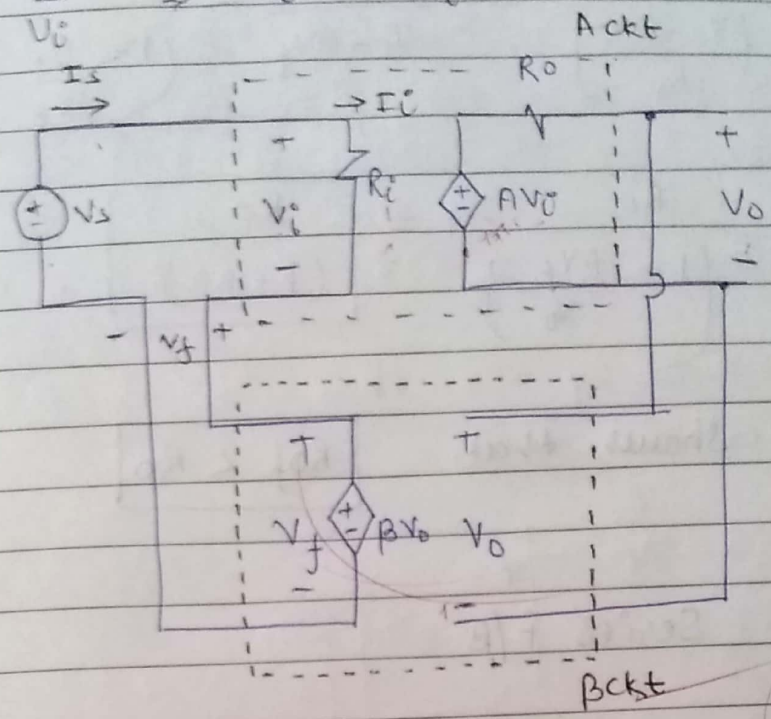
Date: 20/11/19

① Series shunt F/B Amp<sup>r</sup> :-





$$A = \frac{V_o}{V_i} \Rightarrow V_o = AV_i$$



$$\beta = \frac{V_f}{V_o}$$

$$V_f = \beta V_o$$

$$R_{if} = \frac{V_s}{I_s} = \frac{V_i + V_f}{I_i}$$

$$= \frac{V_i}{I_i} \left( 1 + \frac{V_f}{V_i} \right)$$

$$V_i = V_s - V_f$$

$$V_s = V_i + V_f$$

$$I_s = I_i$$

series connection

$$= R_i \left( 1 + \frac{V_f}{V_i} \times \frac{V_o}{V_o} \right)$$

$$\frac{V_f}{V_o} = \beta, \quad \frac{V_o}{V_i} = A$$

$$R_{if} = R_i (1 + A\beta)$$

this shows that  $R_{if} > R_i$

for  $R_{of} \Rightarrow$

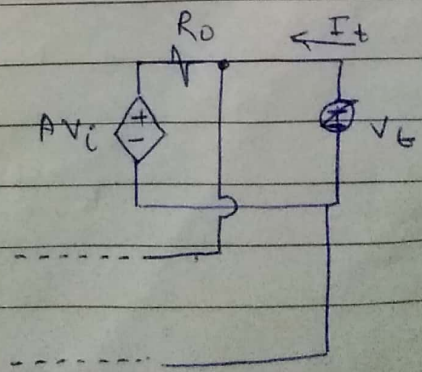
$$V_s = 0$$

$$V_i = V_s - V_f$$

$$V_i = -V_f$$

if we calculate output resistance than input voltage will be zero.

$$R_{of} = \frac{V_t}{I_t}$$



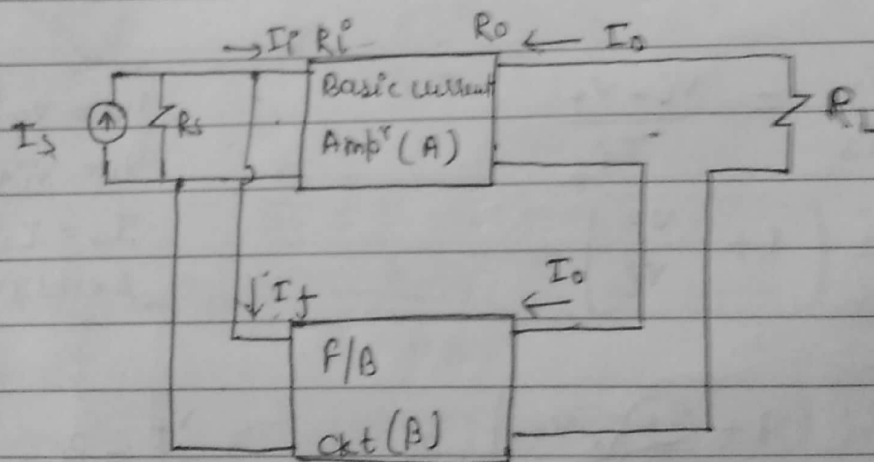
$V_t =$  test voltage  
 $I_t =$  test current

$$R_{of} = \frac{V_E}{\left(\frac{V_E - AV_f}{R_o}\right)} = \frac{R_o V_E}{V_E + AV_f} = \frac{R_o}{\left(1 + \frac{AV_f}{V_E}\right)}$$

$$R_{of} = \frac{R_o}{\left(1 + \frac{AV_f}{V_o}\right)} = \boxed{\frac{R_o}{(1 + AB)}}$$

It shows that  $R_{of} < R_o$

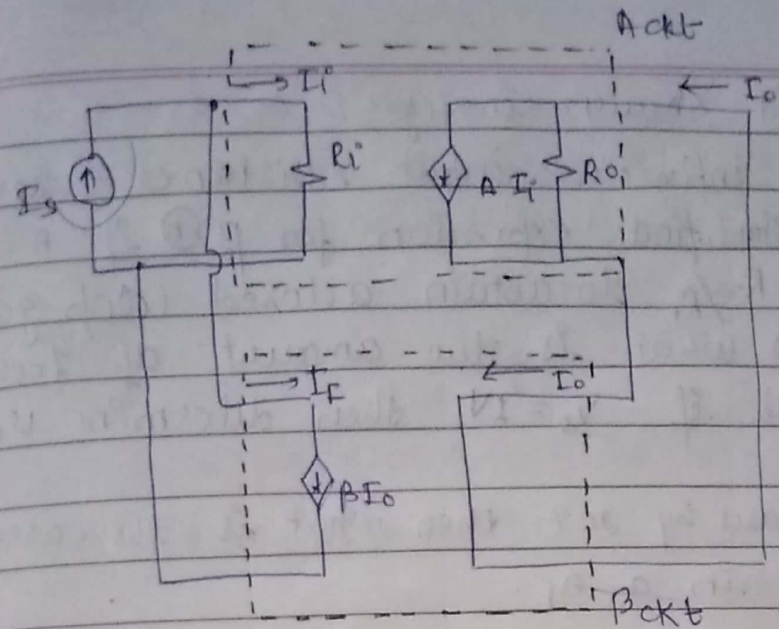
## 2. Shunt Series F/B



$$A = \frac{I_o}{I_i} \Rightarrow I_o = A I_i$$

$$\beta = \frac{I_f}{I_o} \Rightarrow I_f = \beta I_o$$

$$I_i = I_s - I_f$$



$$R_{if} = \frac{V_s}{I_s} = \frac{V_i}{I_i + I_f} = \frac{V_i}{I_i \left(1 + \frac{I_f}{I_i}\right)} = \frac{R_i}{1 + \frac{I_f}{I_i} \times \frac{I_o}{I_o}}$$

$$R_{if} = \frac{R_i}{(1 + AB)}$$

$$R_{if} < R_i$$

for  $R_{of}$

$$I_s = 0$$

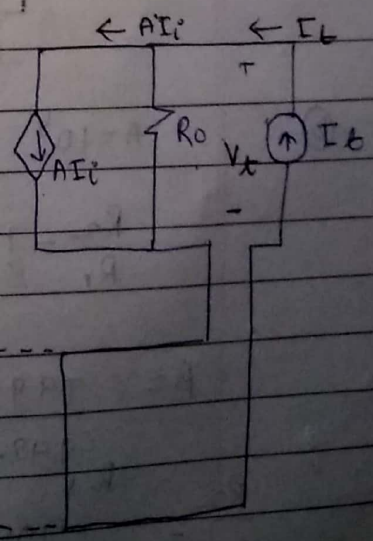
$$I_i = I_s - I_f$$

$$I_i = -I_f$$

$$R_{of} = \frac{V_t}{I_t} = \frac{(I_t - AI_i) R_o}{I_t}$$

$$= R_o \left(1 + \frac{AI_f}{I_t}\right)$$

$$= R_o \left(1 + \frac{AI_f}{I_o}\right)$$

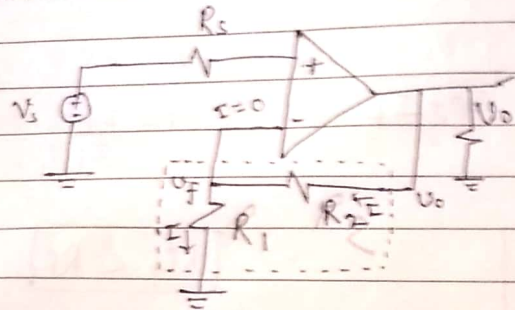


$$R_{of} = R_o (1 + AB)$$

this eq shows

$$R_{of} > R_o$$

- Q. for circuit shown in fig.
- (a) Operate as infinite input resistance zero output resistance find expression for  $\beta$  if  $A = 10^4$  then find  $R_2/R_1$  to obtain closed loop gain of 10. (b) what is the amount of feedback in decibel if  $V_s = 1V$  then determine  $V_o, V_f$  &  $I_f$
- (c) if  $A$  decreases by 50% then what is the corresponding decrement in a AF.



(a)

$$V_f = V_o - I R_2$$

$$V_f = \frac{V_o R_1}{R_1 + R_2}$$

$$\beta = \frac{V_f}{V_o} = \frac{R_1}{R_1 + R_2}$$

(b)  $A = 10^4$

$$A_f = 10 = \frac{A}{1 + A\beta}$$

$$\Rightarrow 10 = \frac{10^4}{1 + 10^4 \beta}$$

$$\beta = \frac{999 R_1}{999 + 9000 R_2} = 1 + 10^4 \beta = 10^3$$

$$\beta = \frac{10^3 - 1}{10^4} = \frac{999}{10^4} = 0.0999$$

$$\frac{R_2}{R_1} = \frac{9001}{999}$$

$$\frac{R_2}{R_1} = 9.01$$

(c)  $1 + A\beta = 10^3$   
 $20 \log (1 + A\beta) = 20 \log 10^3$   
 $= 60 \text{ dB}$

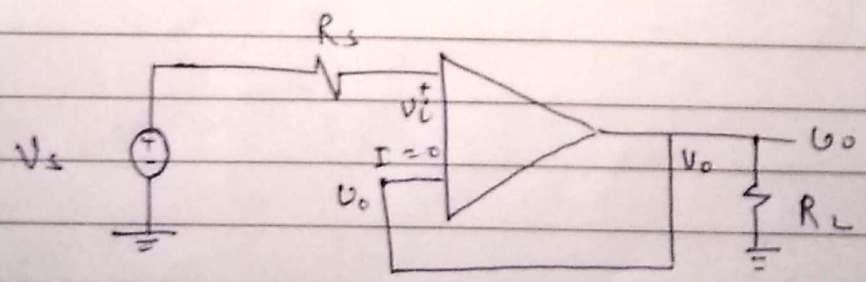
(d)  $V_s = 1$   
 $V_o = A_f V_s = 10 \text{ V}$   
 $V_f = \beta = 10 \times 0.099 = 0.999 \text{ V}$   
 $V_i = V_s - V_f = 1 - 0.999$   
 $= 0.001 \text{ V} = 1 \text{ mV}$

(e)  $\frac{dA}{A} = 20\%$

$\frac{dA_f}{A_f} = \frac{1}{(1 + A\beta)} \frac{dA}{A}$   
 $= \frac{1}{10^3} \times 20\%$

drift  $\frac{20}{1000} = 0.02\%$

Ans-2



Question same as first question.

$\beta = 1 = \frac{V_f}{V_o} = \frac{V_o}{V_o} = 1$

if gain is 1 of any circuit impedance matching.

Ques 3

for current Amp<sup>r</sup>  $R_i = 100 \Omega$  &  $R_o = 100 k\Omega$   
 Given that the basic amp<sup>r</sup> gain is 100 and f/b dbt  
 gain is 0.8 then determine input & output  
 resistance with feedback.

$$\beta = 0.8$$

$$A = 100$$

$$R_{if} = \frac{R_i}{(1 + A\beta)}$$

$$R_{of} = R_o (1 + A\beta)$$

$$1 + A\beta = 1 + 100 \times 0.8 = 1 + 80 = 81$$

$$R_{if} = \frac{100}{81}$$

$$R_{of} = 100 \times 81$$

$$= 8100 k\Omega$$

$$R_{if} = 1.2346 \rightarrow$$